

Working With Waveforms

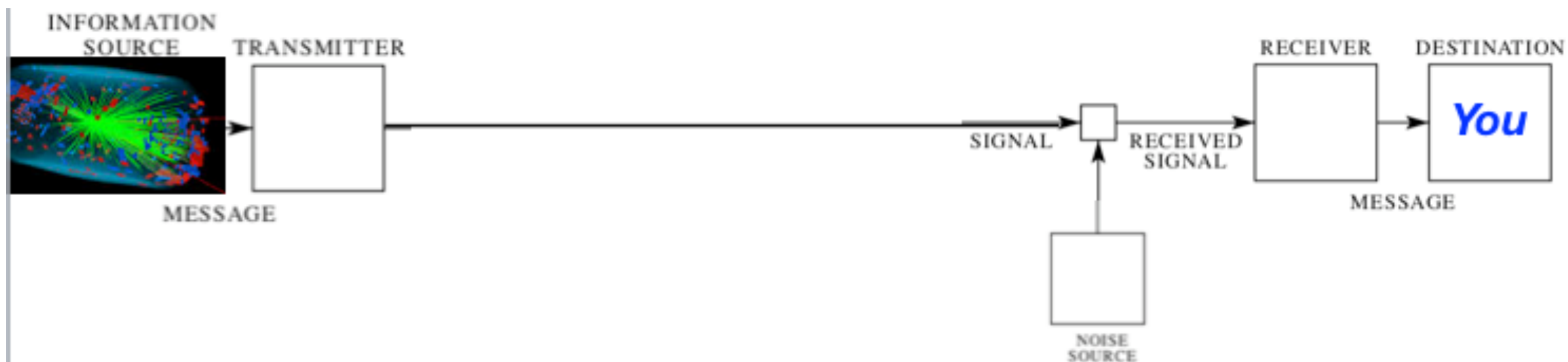
Sebastian White, CERN/U.Virginia Sept. 12, 2018

“ULTIMA 2018”



Argonne National Lab

HL-LHC upgrade program has renewed interest in Charged Particle timing* at $\ll 100$ picosecond resolution. Usually with internal gain.



Acquiring high quality waveforms has been key in PICOSEC sensor development-> $\gg 10^6$ events from MPGD,Silicon,MCP over 4 years

In this talk I will describe methodology and illustrate benefits of this approach

- * see “Experimental Challenges of the European Strategy for Particle Physics”,SNW
- * CHEF 2013- Paris April 2013, http://inspirehep.net/record/1256027/files/CHEF2013_Sebastian_White.pdf

10 Years of waveform analysis from 40 MSa/s to 40 GSa/s

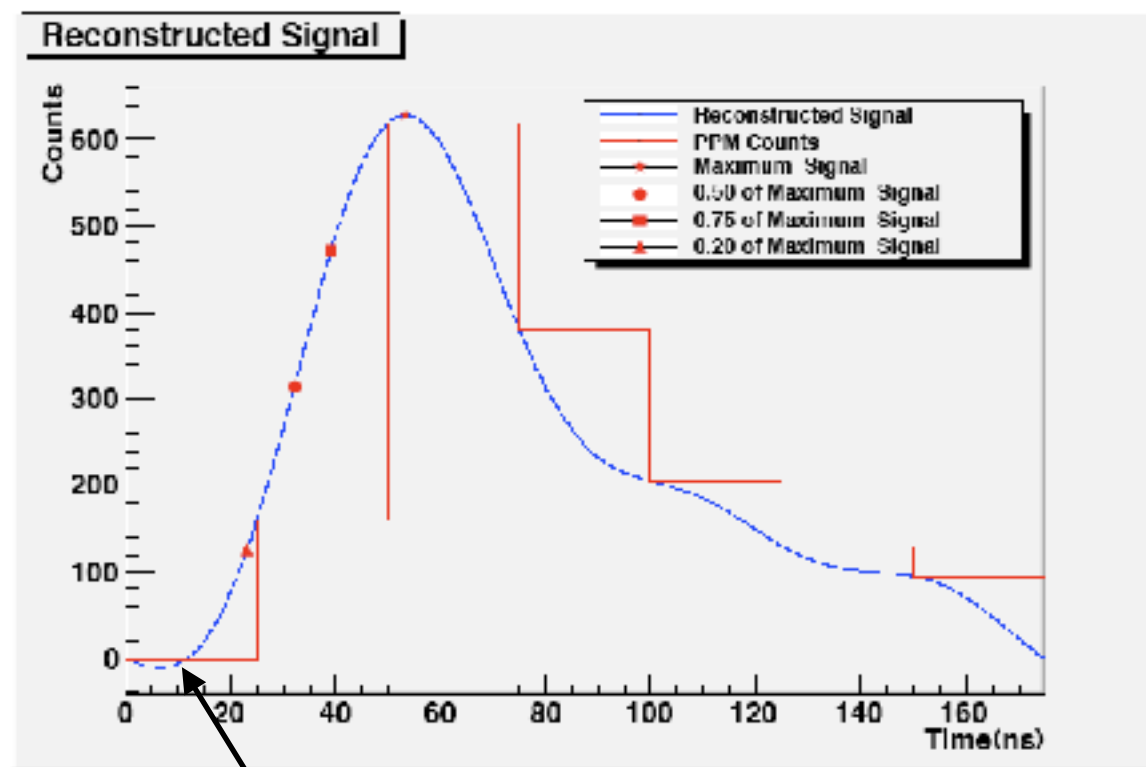
~2010 ATLAS ZDC waveforms
reconstructed from PPM samples
-> sub- 100 picosec resolution

SNW, Diffraction 2010 <https://arxiv.org/abs/1101.2889>
<http://library.wolfram.com/infocenter/Articles/7716/>

Aug. 2018 PICOSEC Test Beam
MCP* ref. time, HyperFastSilicon

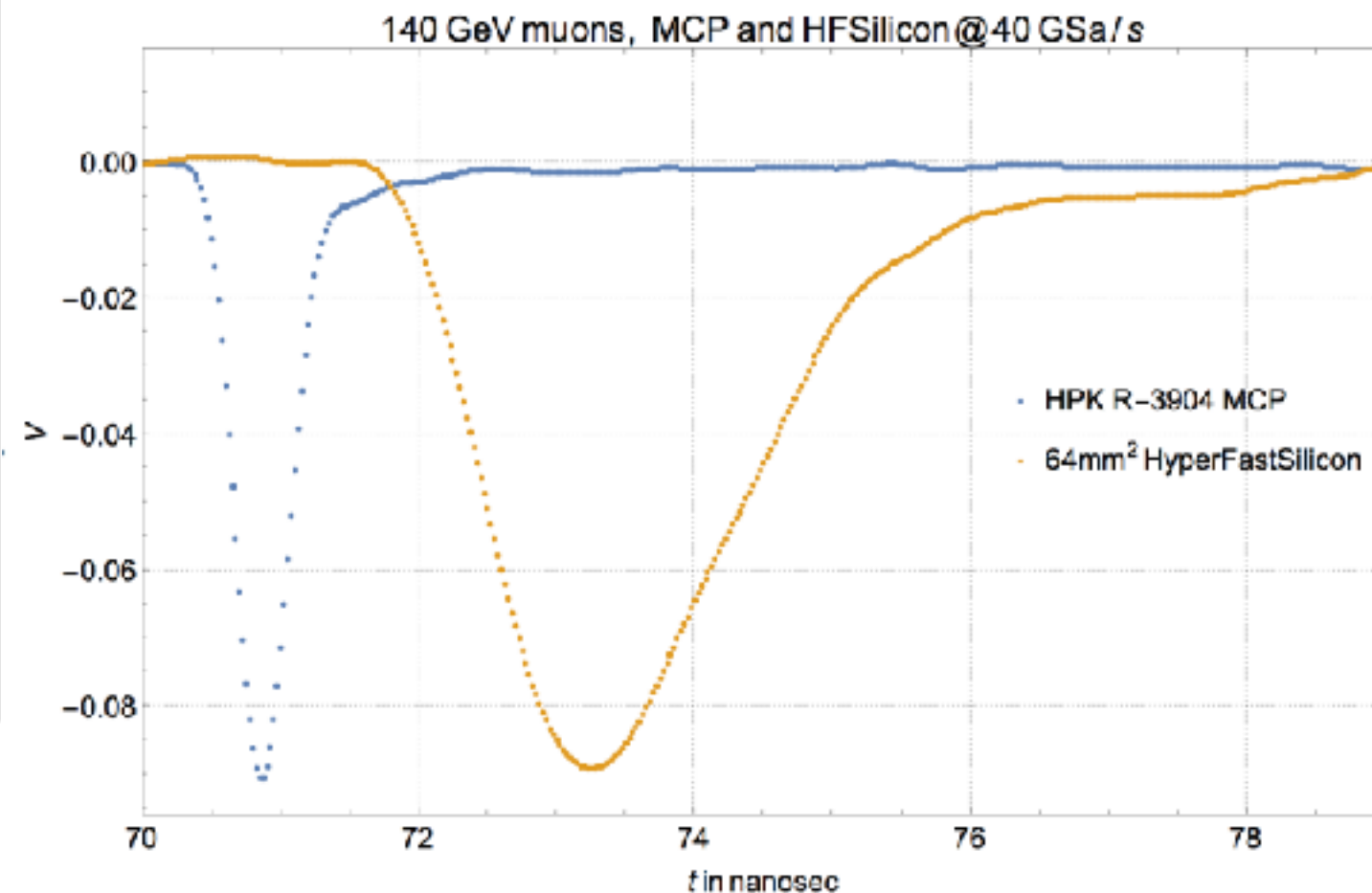
$$\sigma_t^{\text{MCP}} \sim 4 \text{ picosec}, \sigma_t^{\text{HFS}} \sim 20 \text{ picosec}$$

LRS "Wavemaster"



$\frac{\sin[x]}{x}$ interpolation of digitized waveform

$$\text{shannon}[t] = \sum_{i=1}^{n_{\text{slice}}} \text{slice}[i] \times \text{Sinc}[\pi \times (t - \text{time}(i))/25)] \quad (6)$$



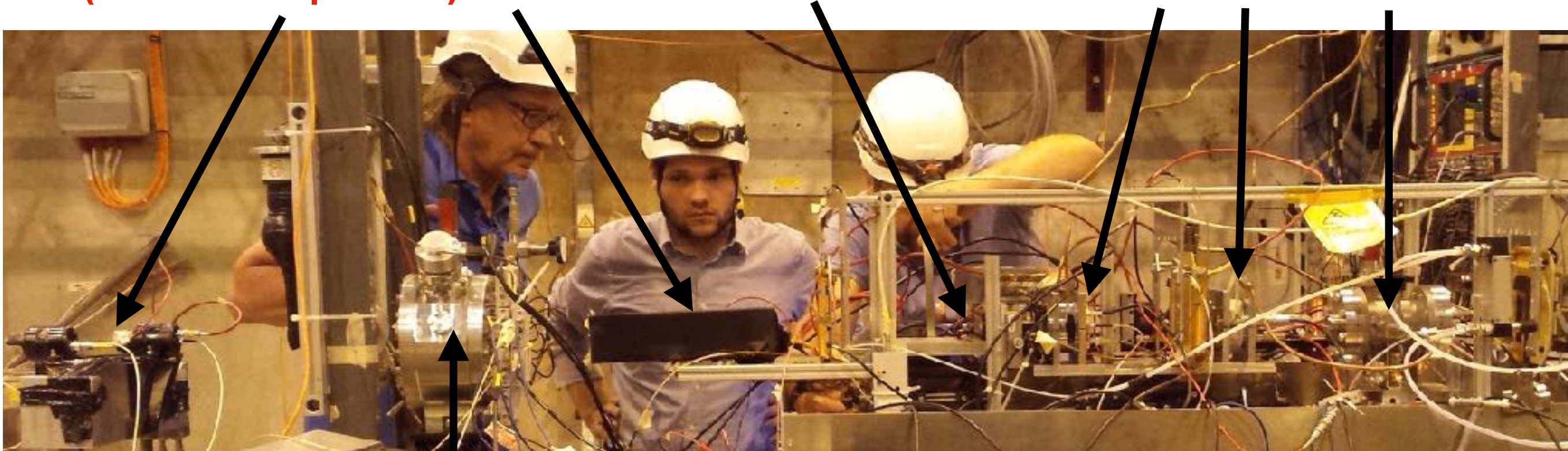
* MCP= MicroChannel PMT
detecting Cerenkov from window

July/Aug 2017 PICOSEC data

4x 6micron HPK MCP 's
+3mm Quartz
(measure ~4 picosec)

HyperFastSilicon(HFS)
(mesh readout DD-AD)
64 mm²/pixel
(measure<20 picosec)

MMegas-based
"PICOSEC"
80 mm² pixel
(measure<25 picosec)

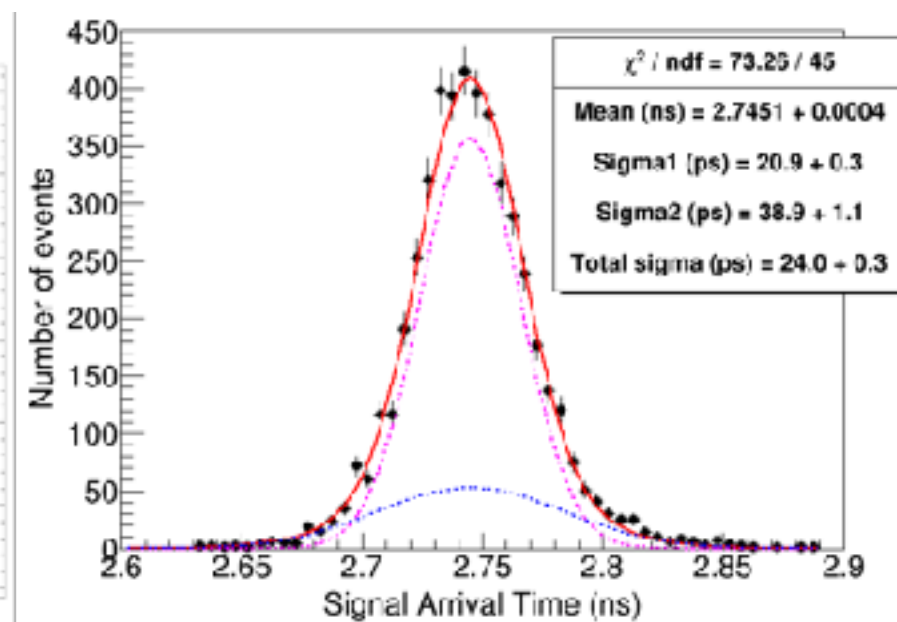
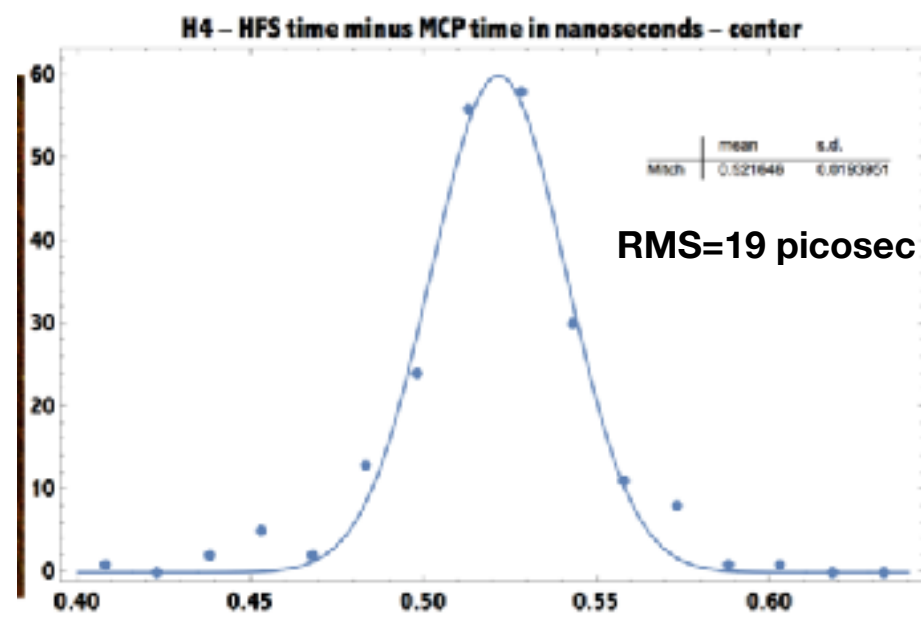
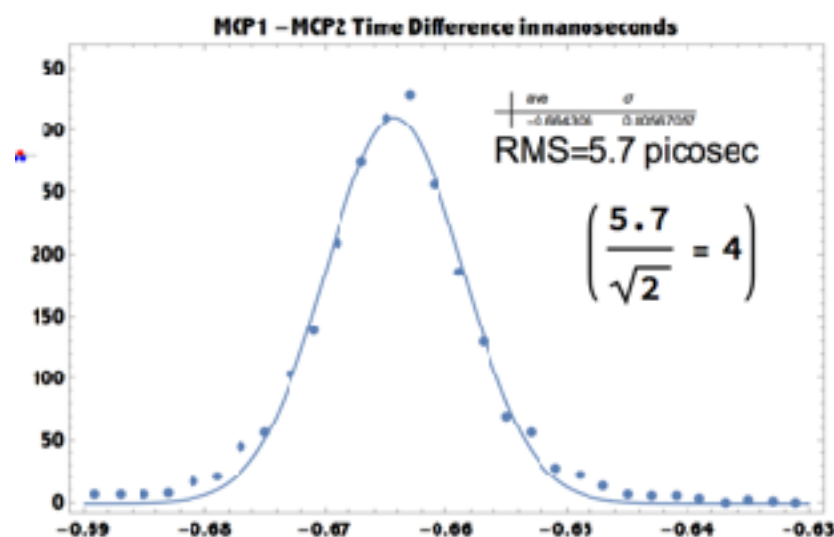


10 pad "PICOSEC"

Si- Gallium doped

Ne/C₂H₆/CF₄

vacuum



2 Fast Timing Projects based at CERN (we share resources, beam, ++)

PICOSEC: RD51 common Fund proposal in 2014 by SNW and I. Giomataris

MPGD

J. Bortfeldt^b, F. Brunbauer^b, C. David^b, D. Desforge^a, G. Fanourakis^e, J. Franchi^b,
M. Gallinaro^g, I. Giomataris^a, D. González-Díazⁱ, T. Gustavsson^j, C. Guyot^a, F.J. Iguaz^{a,*},
M. Kebbiri^a, P. Legou^a, J. Liu^c, M. Lupberger^b, O. Maillard^a, I. Manthos^d, H. Müller^b,
V. Niaouris^d, E. Oliveri^b, T. Papaevangelou^a, K. Paraschou^d, M. Pomorski^k, B. Qi^c,
F. Resnati^b, L. Ropelewski^b, D. Sampsonidis^d, T. Schneider^b, P. Schwemling^a, L. Sohl^{b,1}, M.
van Stenis^b, P. Thuiner^b, Y. Tsipolitis^f, S.E. Tzamarias^d, R. Veenhof^{h,2}, X. Wang^c, S. White^{b,3},
Z. Zhang^c, Y. Zhou^c

new paper this week:



Nuclear Instruments and Methods in Physics Research
Section A: Accelerators, Spectrometers, Detectors and
Associated Equipment

Volume 903, 21 September 2018, Pages 317-325



HFSilicon: “Sensors with Internal Gain”-started in 2015

Silicon

M. Centis Vignali¹, M. Gallinaro^{1,2}, B. Harrop³, C. Lu³, M. McClish⁴,
K. T. McDonald³, M. Moll¹, F. M. Newcomer⁵, S. Otero Ugobono^{1,6}, and
S. White^{1,7}

subset originated in 2011 DOE AD R&D award to:



Growing, highly motivated group w. serious commitment to Instrumentation

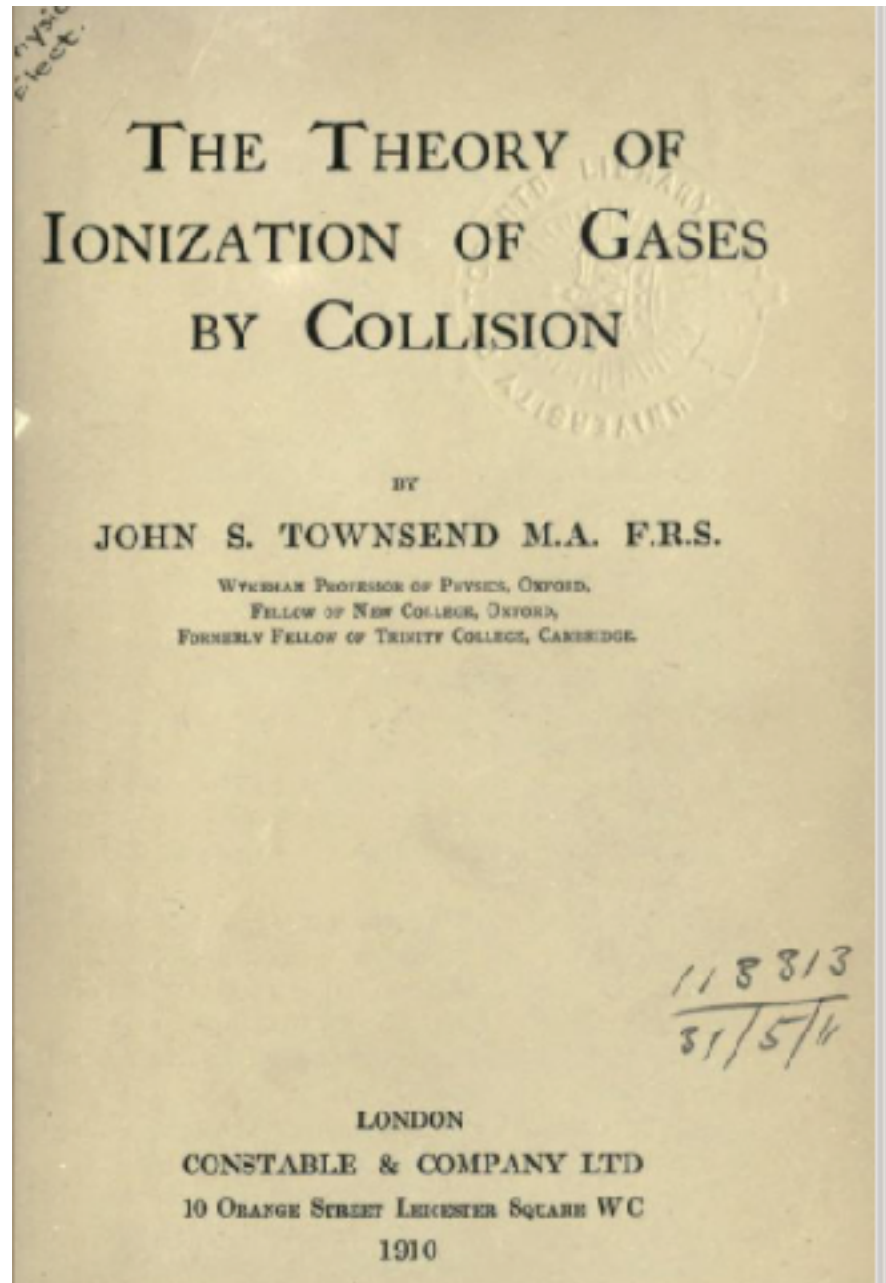


Outline

- 1) **Development of PICOSEC MPGD based detector (24 picosec)**
 - Cerenkov Radiator, similarities to MCP
 - Drift Region-dominant role of diffusion and Gain
- 2) **Application of similar modeling tools (SILVACO) for Silicon (20 picosec)**
 - SILVACO tct-edge scan tool- with Ranjeet Dalal, Delhi
 - realistic Landau/Vavilov- thin samples- with Su Dong, Stanford
- 3) **tools for FEE development**
 - CIVIDEC development -w E.Griesmayer, Vienna
 - Transimpedance amp -w. M. Newcomer(+E.Morales), U. Penn
 - quad fast ASIC (SiGe)- “ “-(w. US/CMS support)
- 4) **Strategies for digitization**
 - CMS Barrel Timing Layer prototype data (LYSO/SiPM)
 - other applications

It Takes Time

**detection/multiplication
in Gas detectors (1910)**



in Silicon detectors(1972)

The distribution of gains in uniformly multiplying avalanche photodiodes: Theory

R.J. McIntyre

IEEE Transactions on Electron Devices

Year: 1972, Volume: 19, Issue: 6

Pages: 703 - 713

Cited by: Papers (271) | Patents (9)

IEEE Journals & Magazines

Factors affecting the ultimate capabilities of high speed avalanche photodiodes and a review of the state-of-the-art

R.J. McIntyre

1973 International Electron Devices Meeting

Year: 1973

Pages: 213 - 216

Cited by: Papers (12)

IEEE Conferences

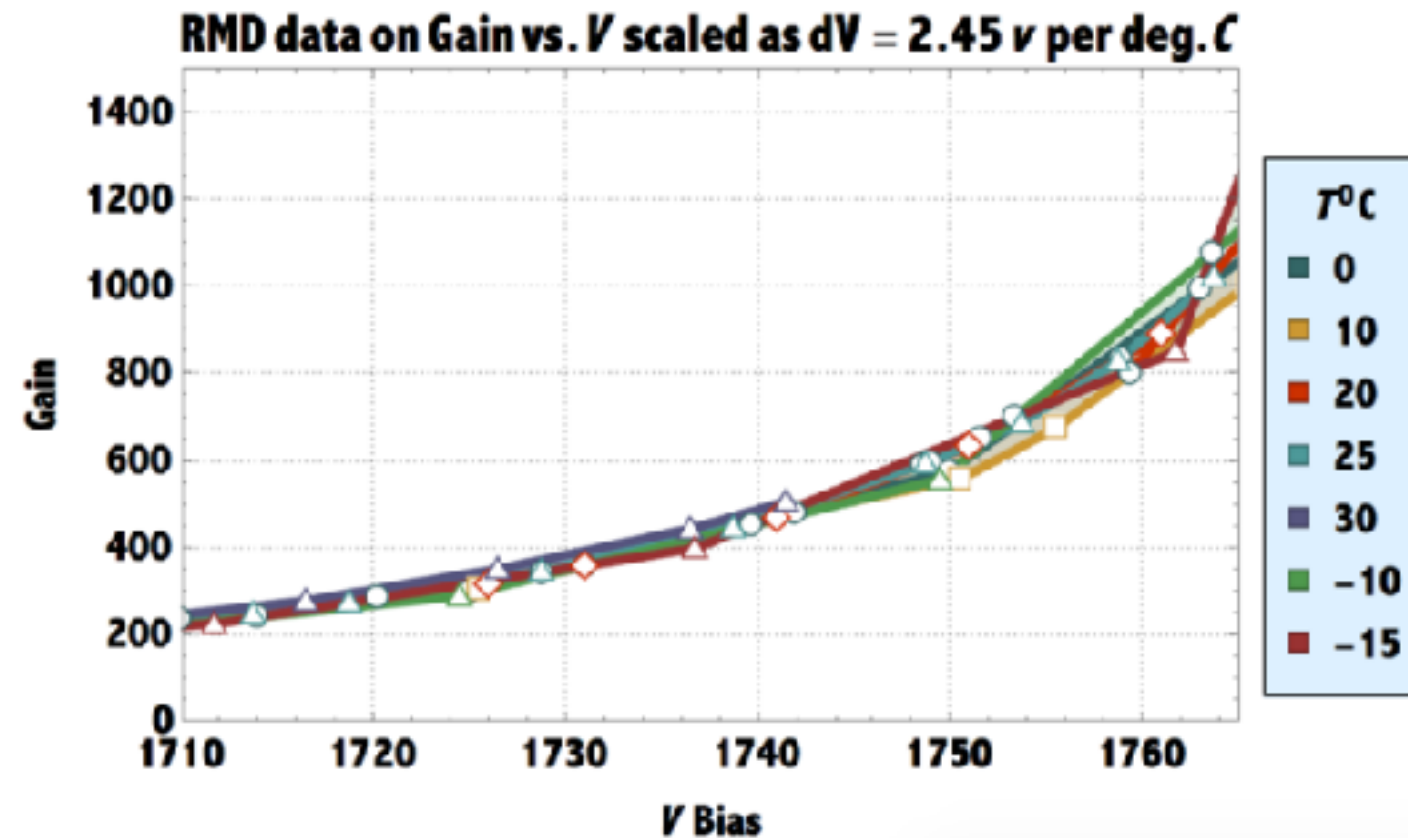
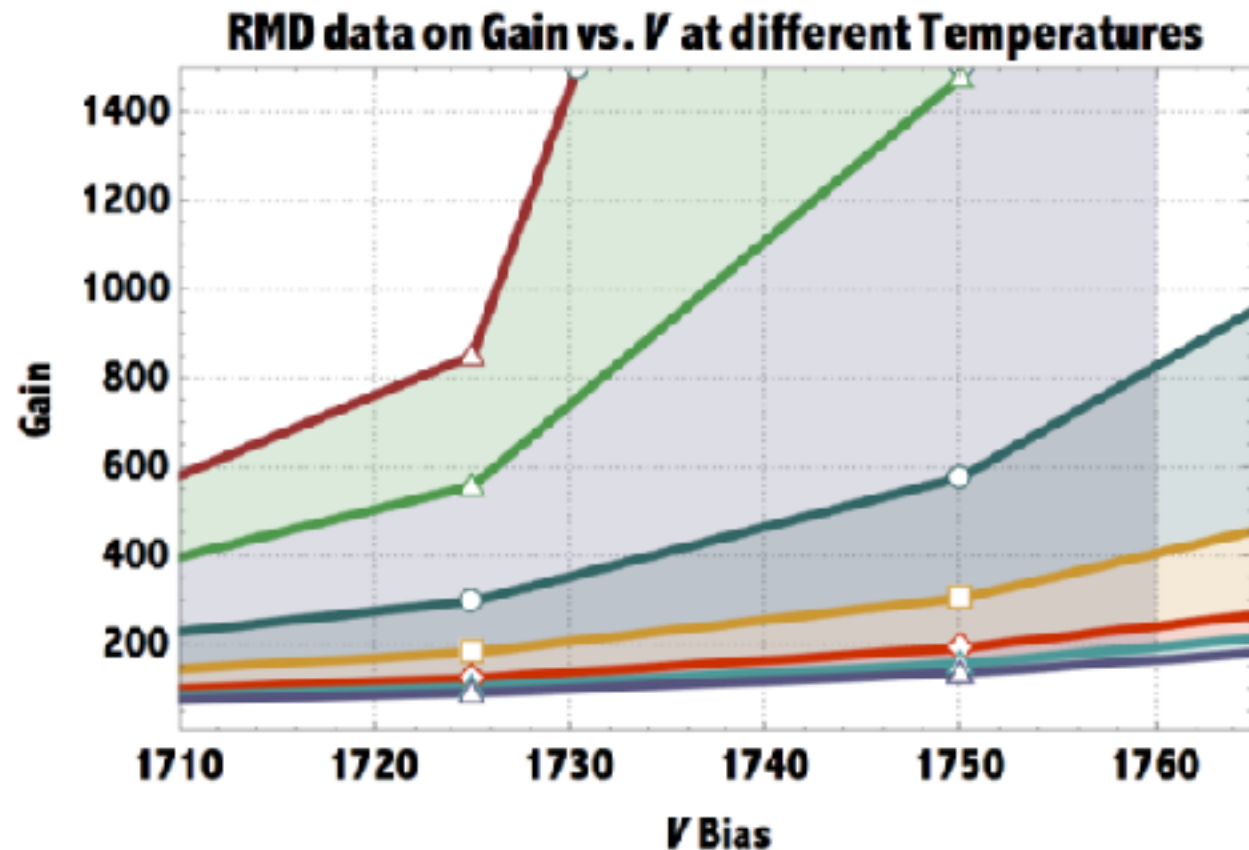
Theory and practice of Si w. internal gain relatively new.

- 1) *most common, “reachthrough” diodes (aka “lgad”) ~1970’s, MIP timing in ’90’s*
 - 2) *higher gain, “deep depleted” (our focus) started in ’90’s*
- cooperative R&D w Gas(RD51) benefitted less mature Si modeling**

ATLAS/CMS timing upgrades all based on Si w gain

->justifies continued development of underpinnings

interesting, possibly deep, phenomena not yet traceable to particular gain model



waveform data may reveal features not anticipated in models

->Si structure modification to mitigate degradation ($\sim x2$) due to Landau?

-> “ “ “ “ degradation due to radiation damage?

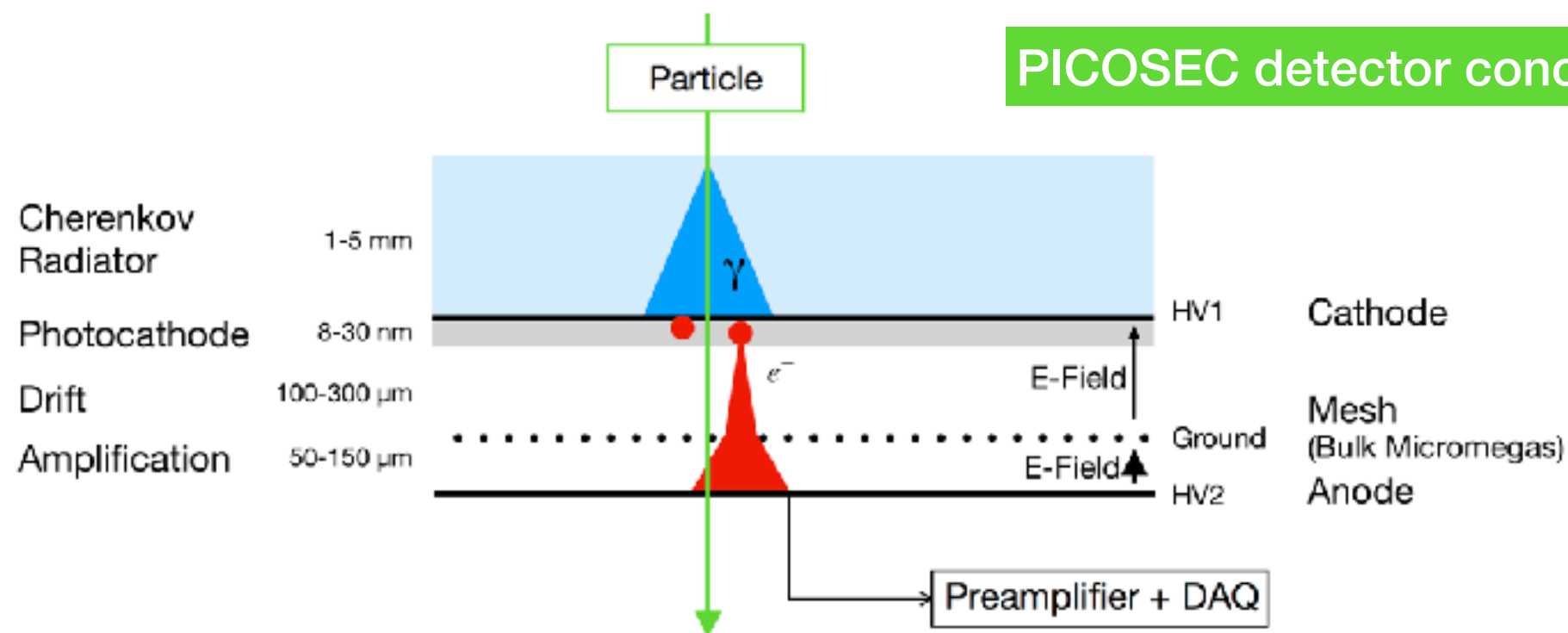
this worked w. PICOSEC (see below)-> then traced to simulation tools

In any case waveform data key in guiding FEE and digitizer strategy.

Ionization or Photodetection?

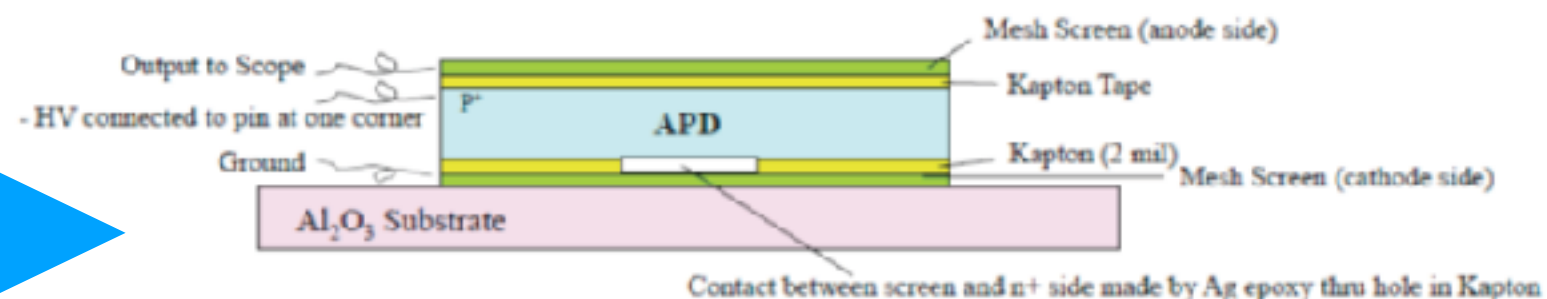
PICOSEC detector concept

note similarity
to MCP (next)

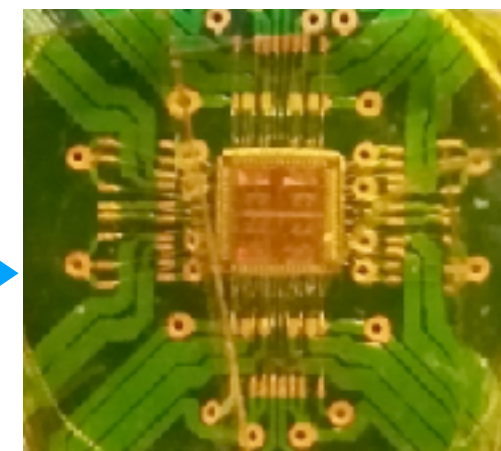
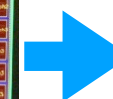
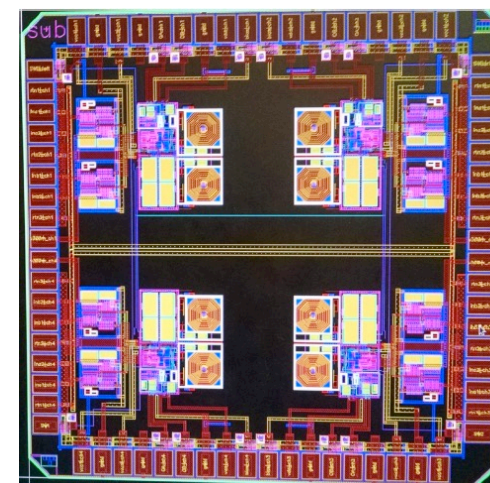
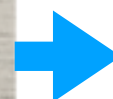


mesh readout deep-depleted AD
aka "HyperFast Silicon"

Top Screen Output Connection (capacitively coupled)

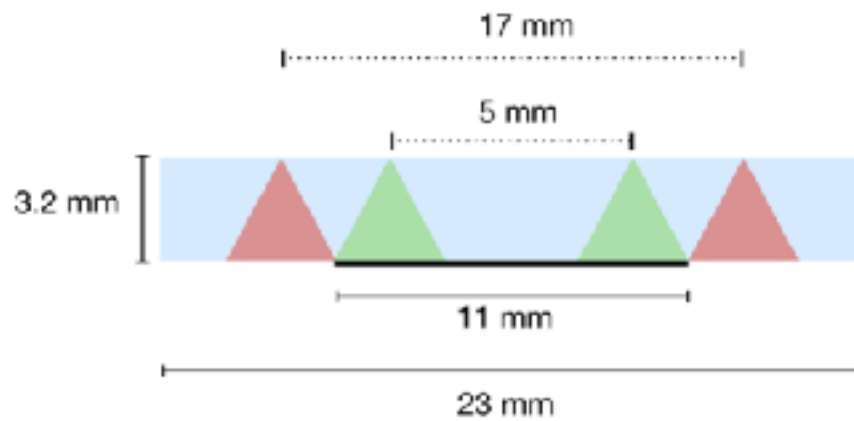


developed discreteTIA in Si/Ge- \rightarrow quad ASIC

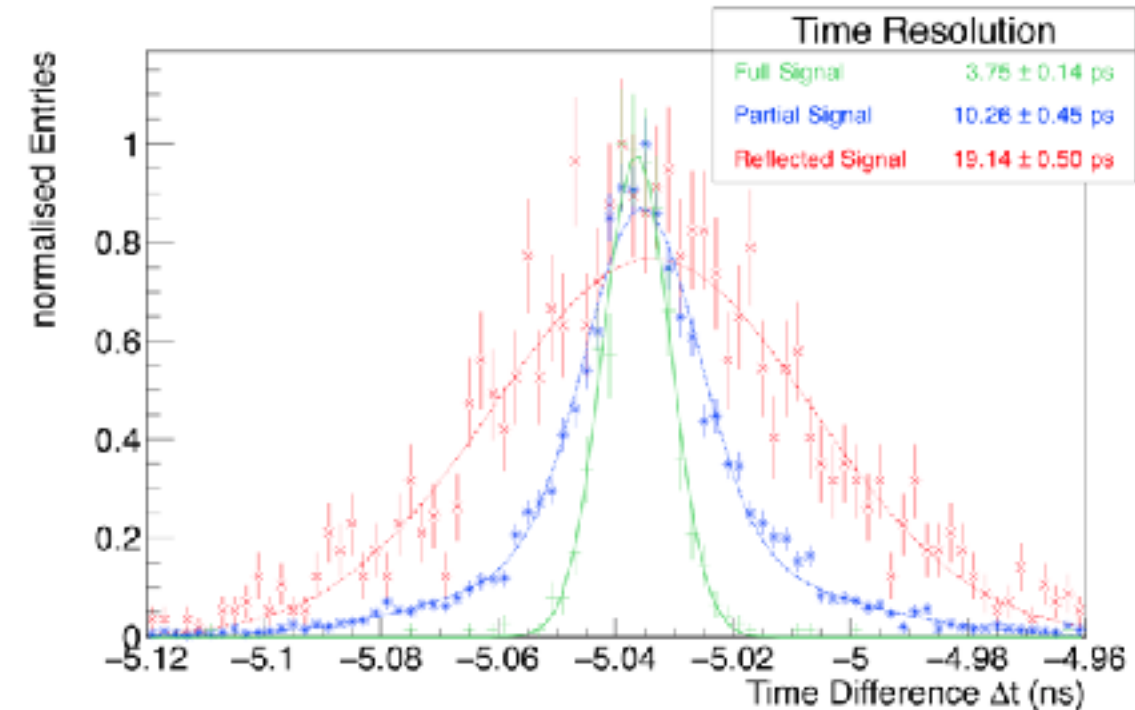
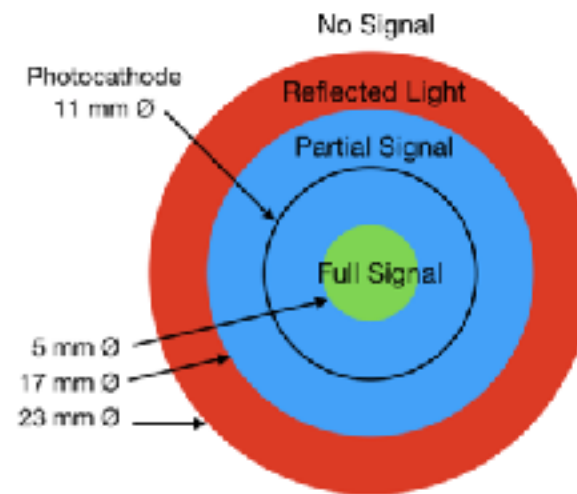


detailed understanding of MCP applies to-> PICOSEC

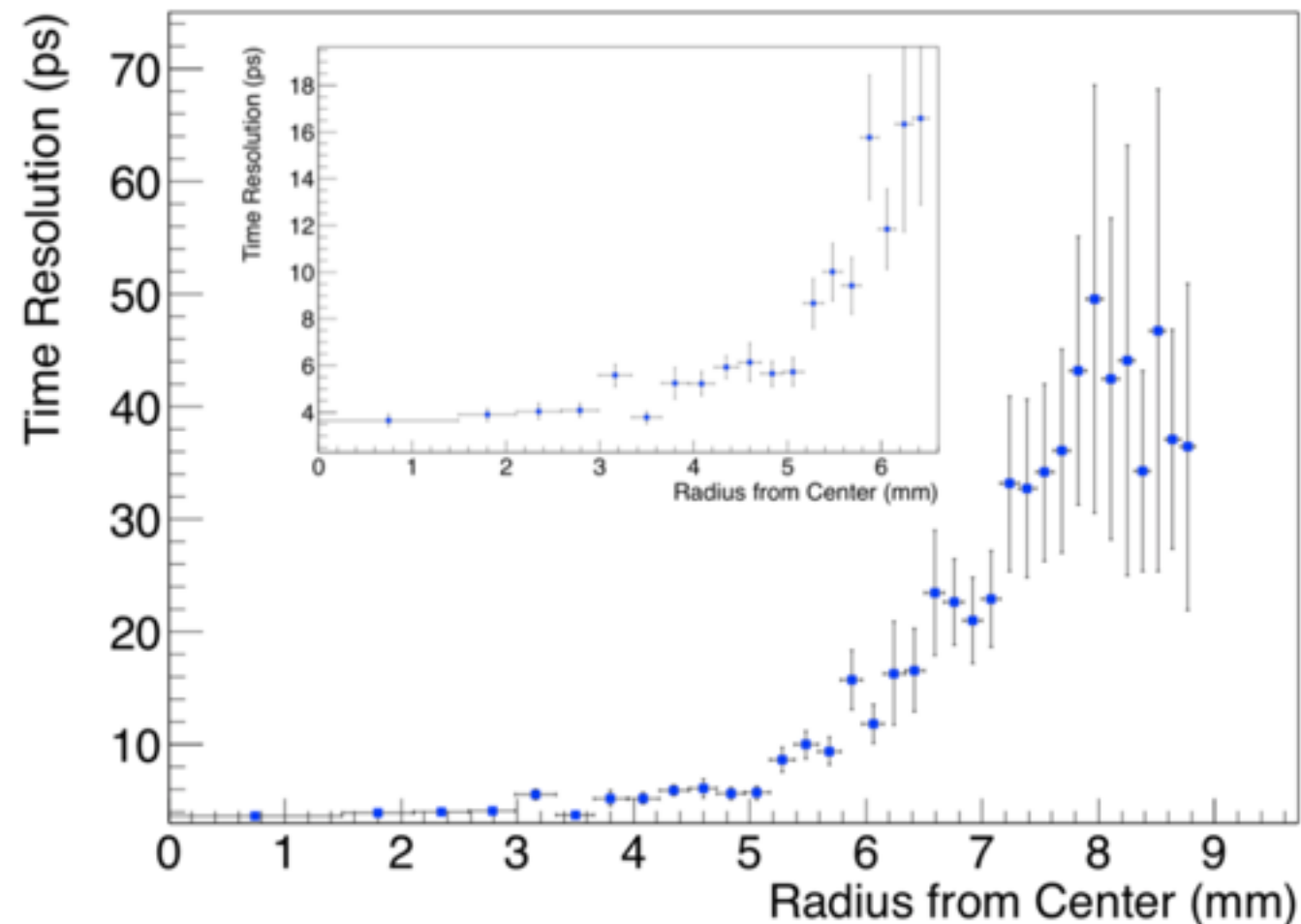
see L. Sohl 2018 Elba



Cerenkov in
HPK MCP window
(note similar
to MMEgas 3mm)

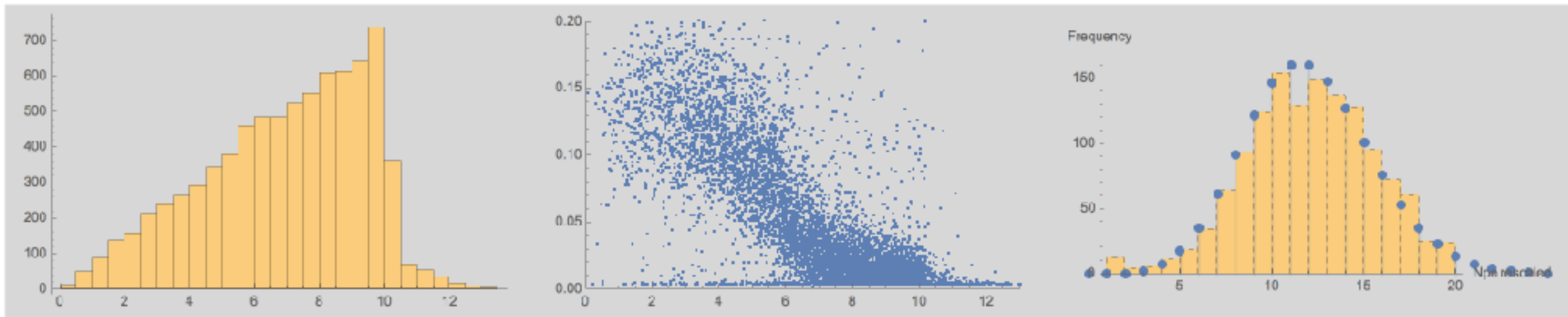


in multi-pad PICOSEC
combine pads to restore
“full signal”



as with MCP, PICOSEC(next) timing with full Cerenkov cone

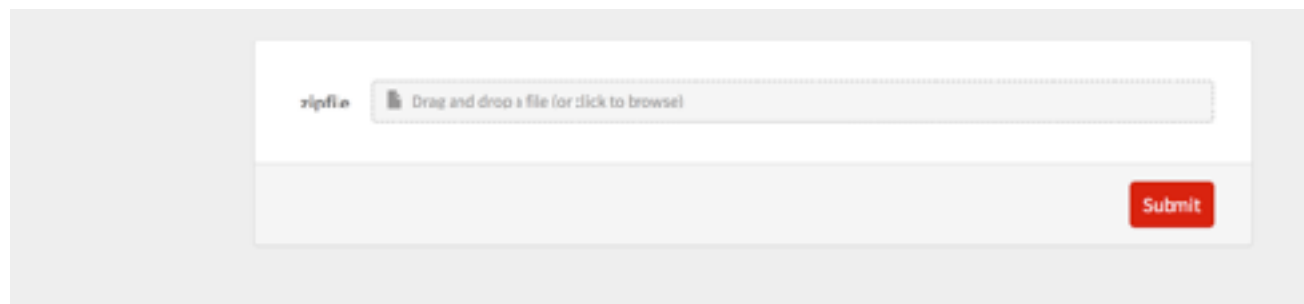
Track Impact for hits above noise in MCP, Peak Amplitude vs. Impact and Peak Distribution for RMCP < 4.5 mm



unlike PICOSEC, MCP response to photoelectrons simple!

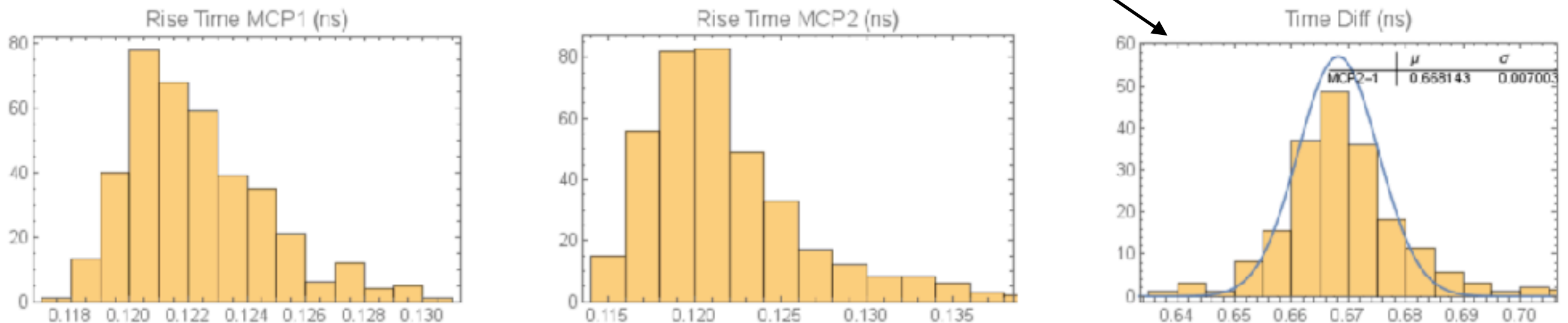
-> tools (in collaboration w Wolfram Research) to do complete analysis in cloud

see. M. Guth talk at DIANA-HEP Oct. 30, 2017



<-drop binary scope file in cloud app

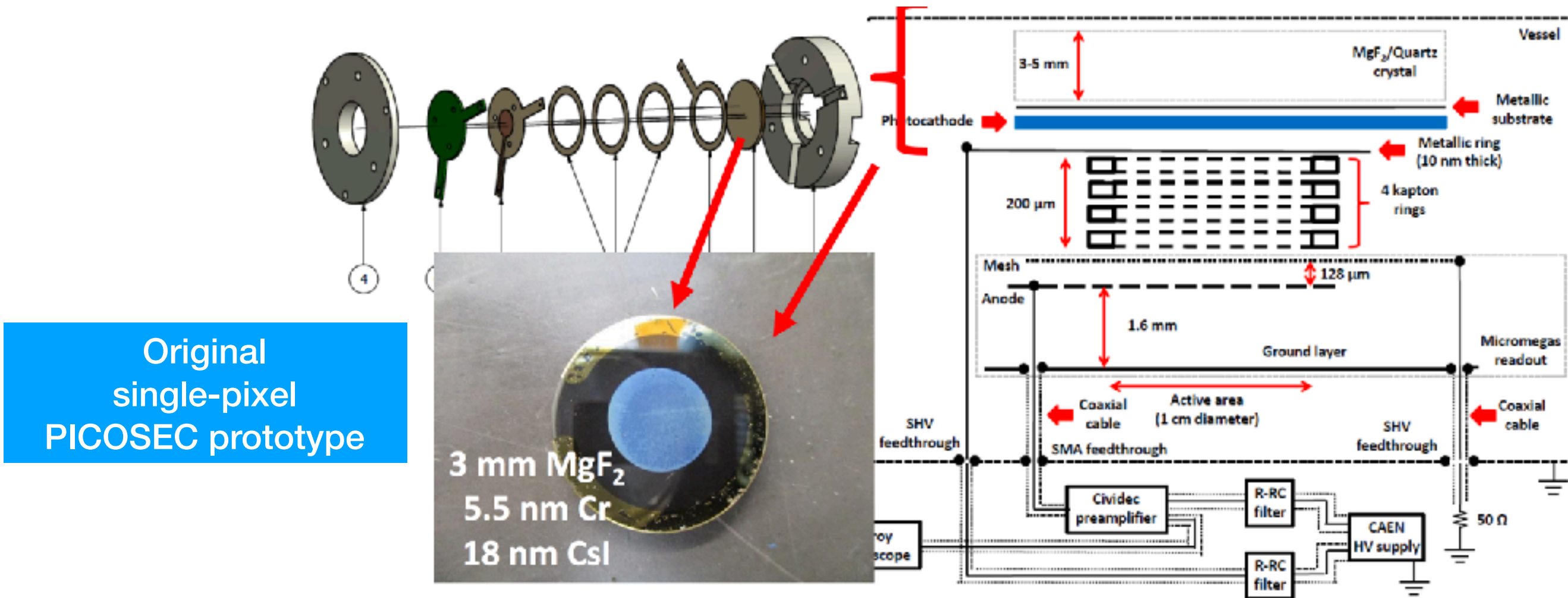
it sends you back report



very good data quality from HFS in 2017!

why initiate something in MPGD?

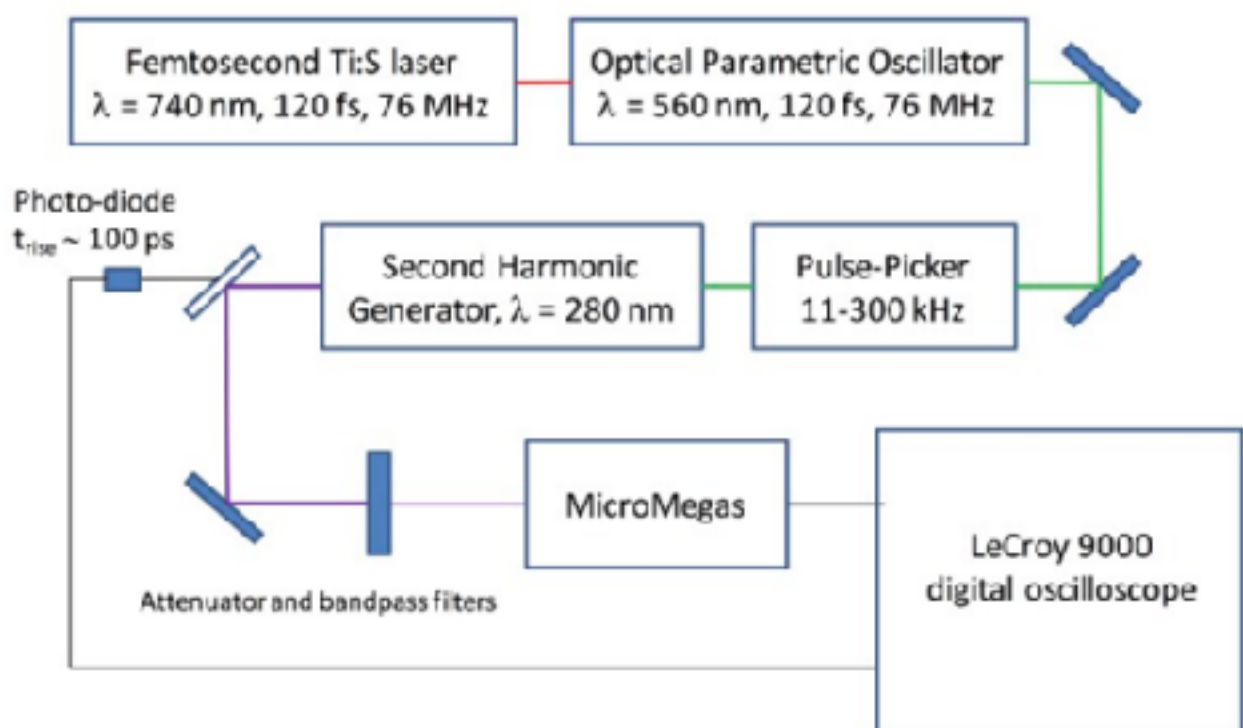
- big enthusiasm in GDD/RD51 because speed ensures continued relevance
- potential benefit of continuous MIP signature (ie no Landau)
- a hedge against rad hardness of Silicon w Internal Gain
- “this seems like the right way to get inexpensive, large area timing”-R. Horisberger



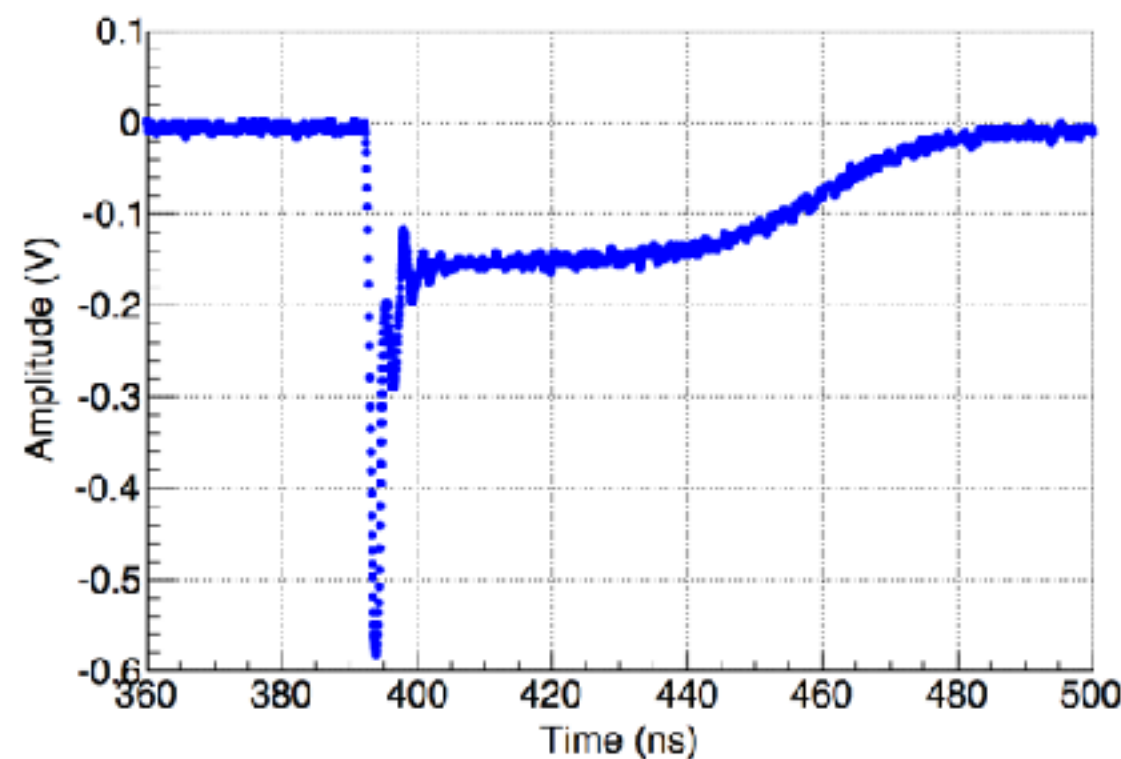
- Main elements:
- Bulk MM readout.
 - 3 kapton rings spacers to define the drift.
 - A crystal + photocathode.

Ongoing Program of laser (for single photoelectron response) and H4 (150 GeV Muon beam)

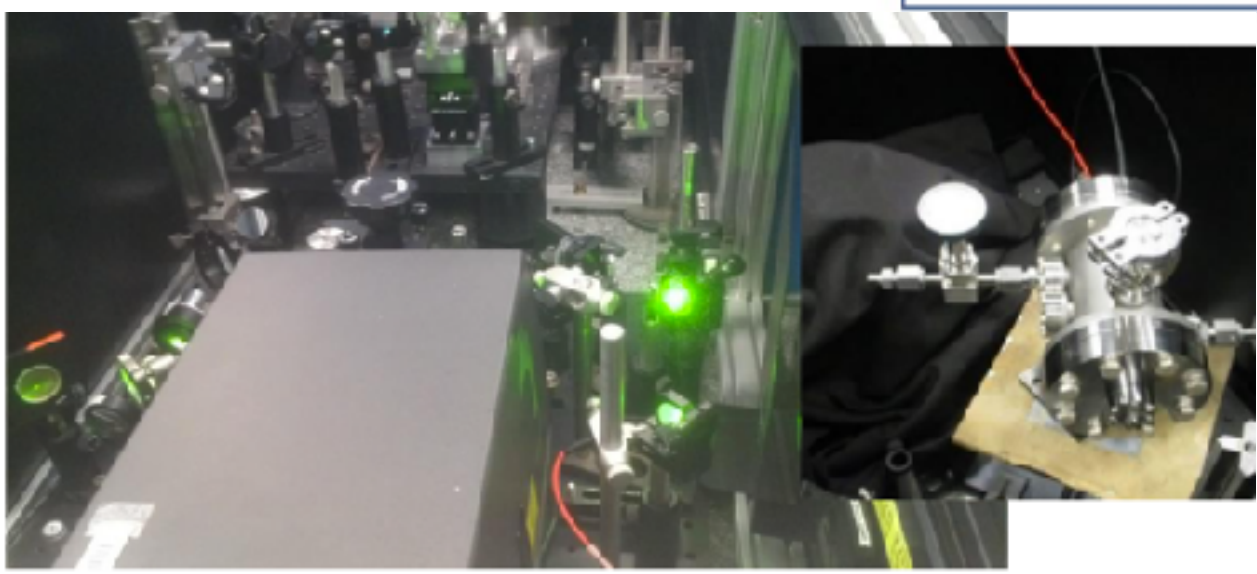
Laser



typical single pe signal w. 40 dB CIVIDEC



we measure signal time-of-arrival from leading edge of fast electron part using “local CF”, Leading edge fit, and full pulse modeling ie corrected for electronic slewing



Gas choice: optimize σ_L and v_{Drift} but favor stability

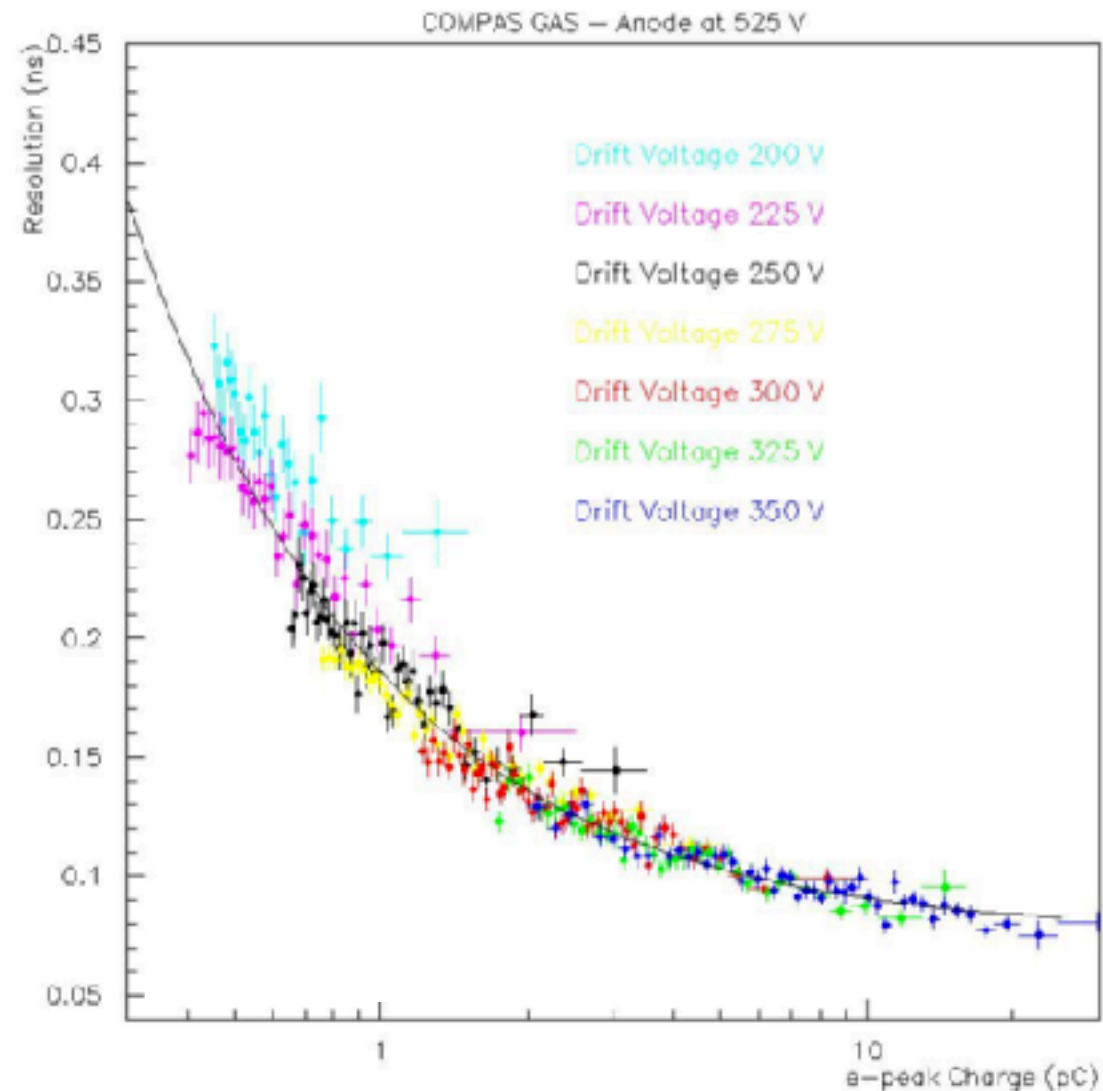
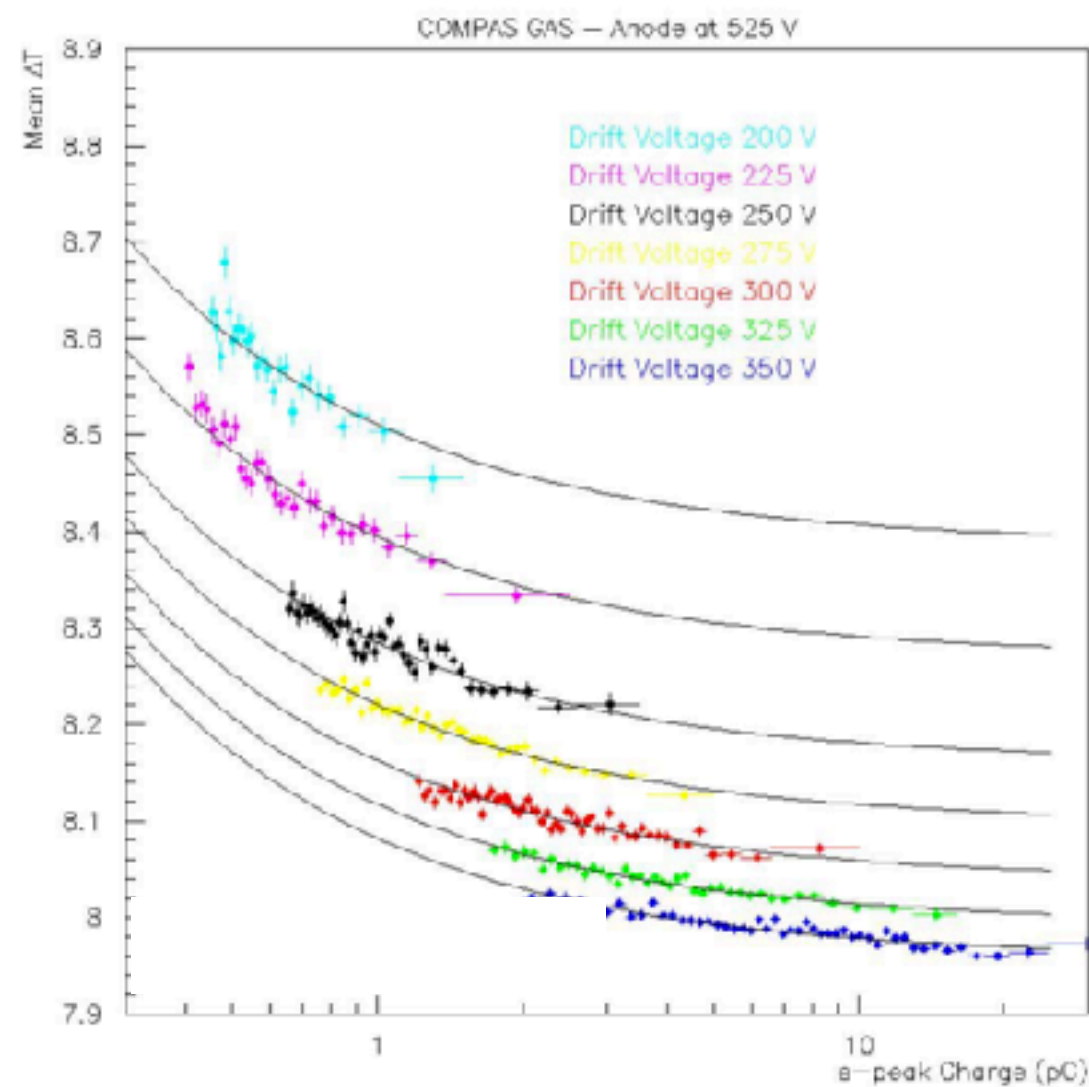


several CF4+ quencher
Ne/Ethane/CF4
mostly showing 90:10:10

Expectation that
Preamp Gain in drift
-> mitigate σ_L
see following

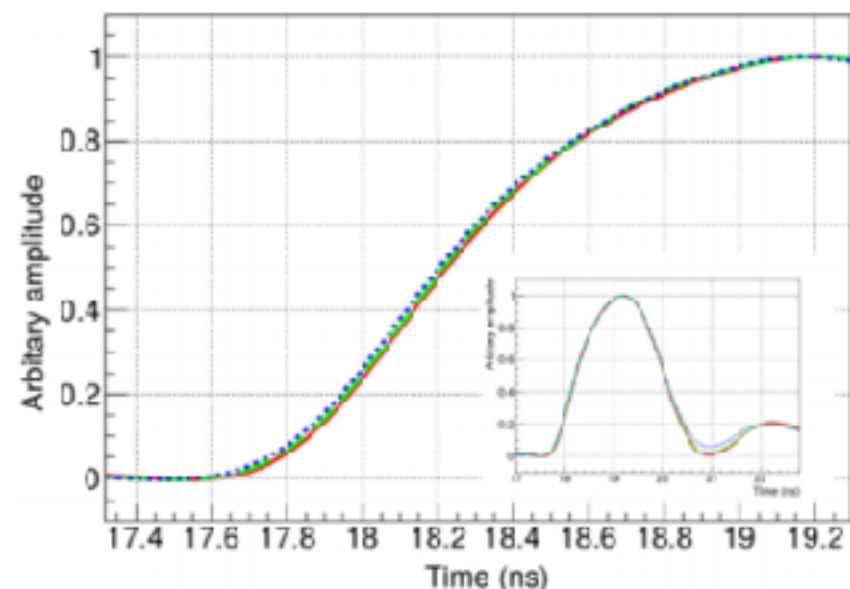
Key to MIP performance is: time-of-arrival and jitter vs. single pe signal

“Compass Gas”=Ne/Ethane/CF₄ 90:10:10

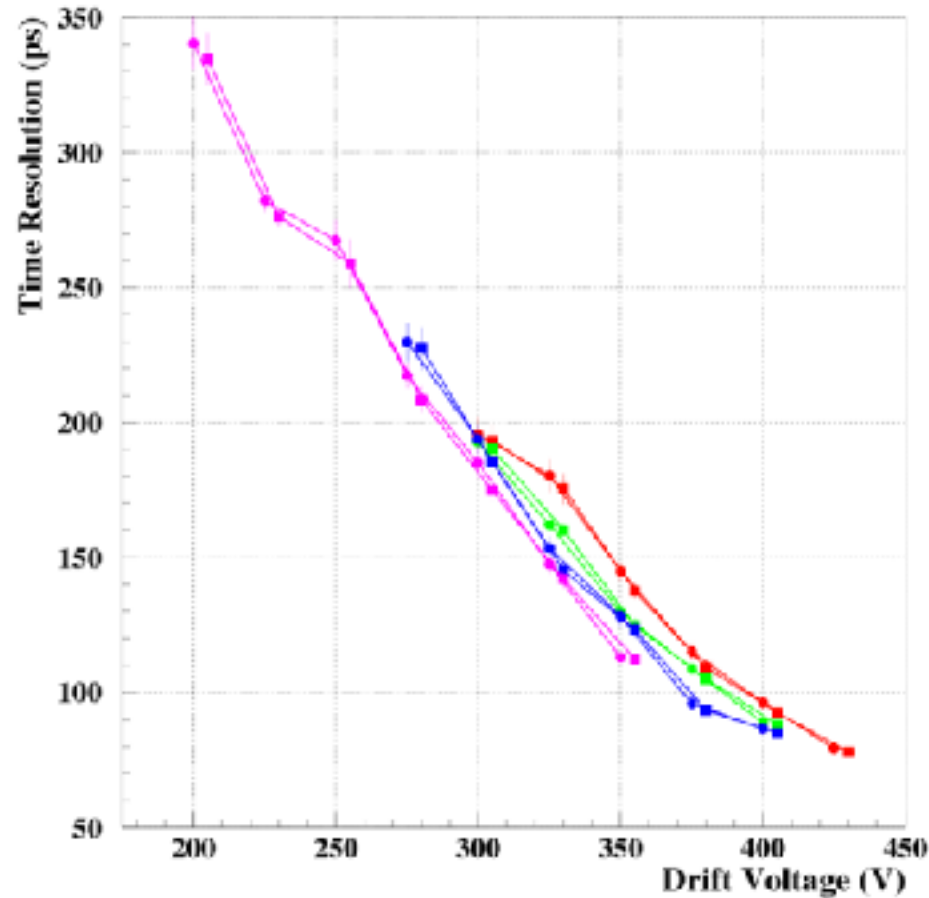


above dT “time-walk” corrected
->residual shift from physics of Gain

whole waveform shifts
slices of Gain (by factor 4) — — ->



Summary of selected Single pe and MIP timing PICOSEC (July, Aug, Oct 2017)



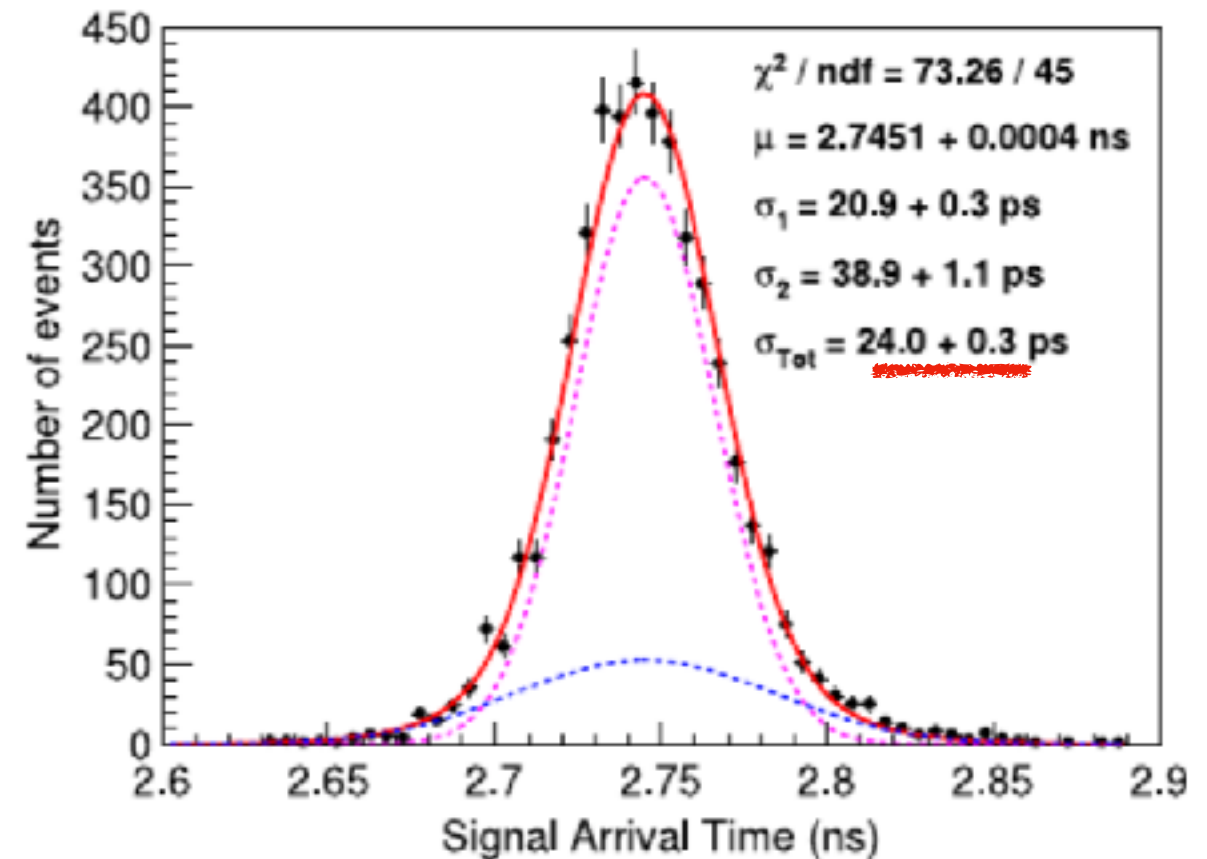
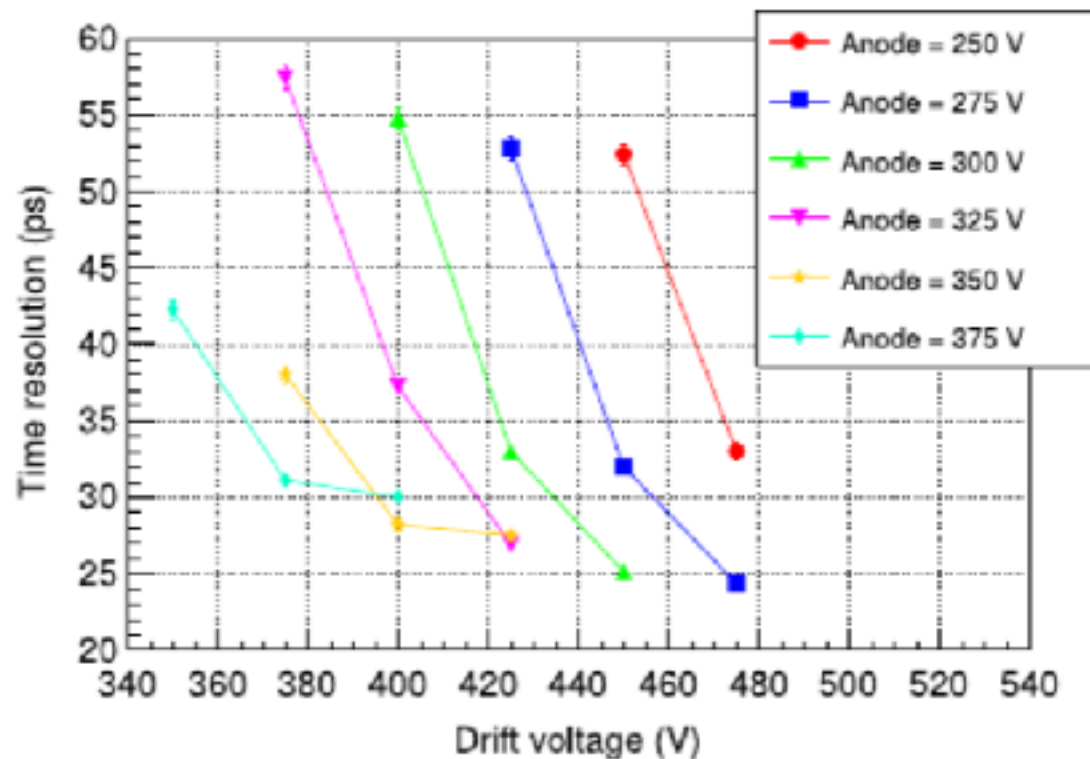
consistency between
 <— — — single pe
 and

150 GeV Muon results

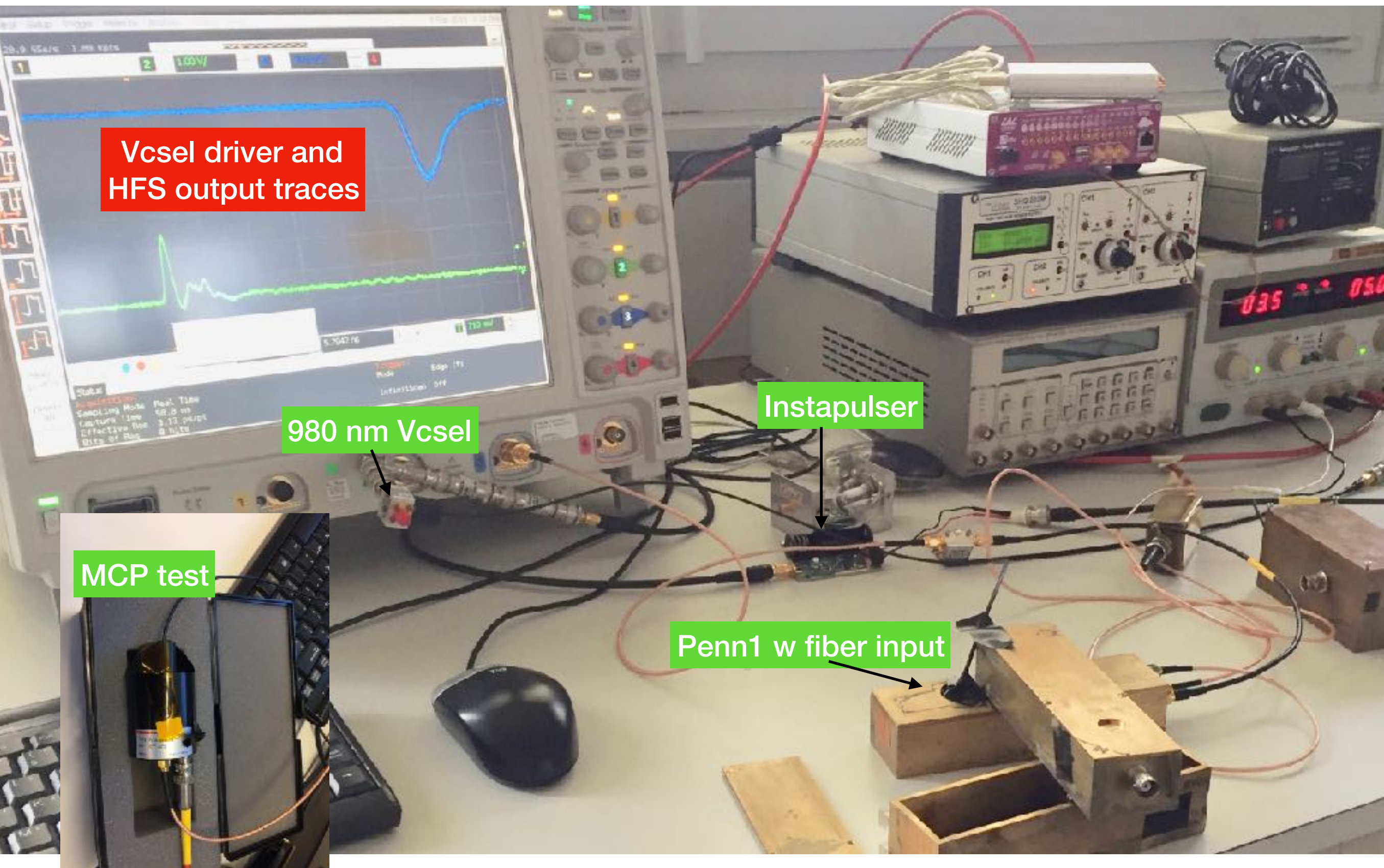
$\langle N_{pe} \rangle \sim 10$

many similarities
 between PICOSEC
 and HFS
 mutually beneficial

H4 Testbeam resolution(PICOSEC)



HyperFast Silicon: low cost laser , 1 MeV e-source, 140 MeV muon beam



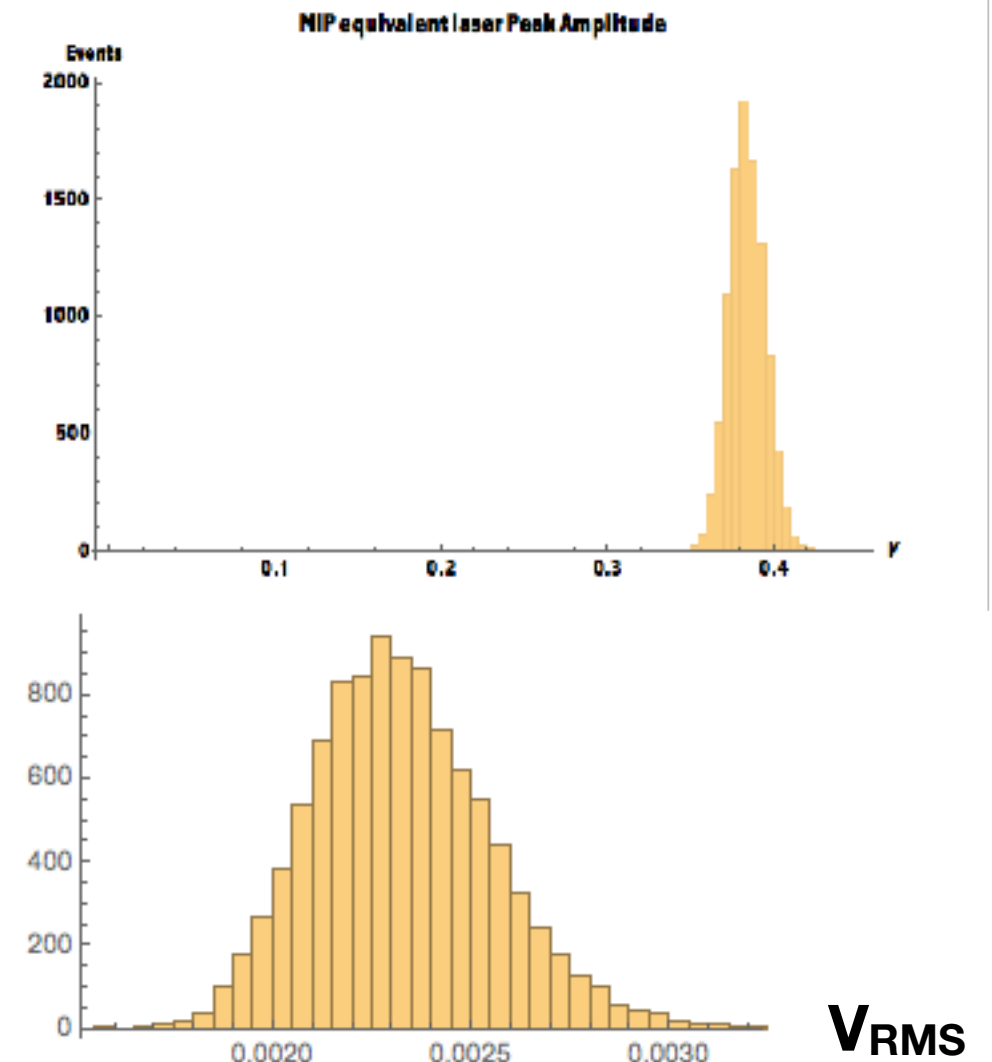
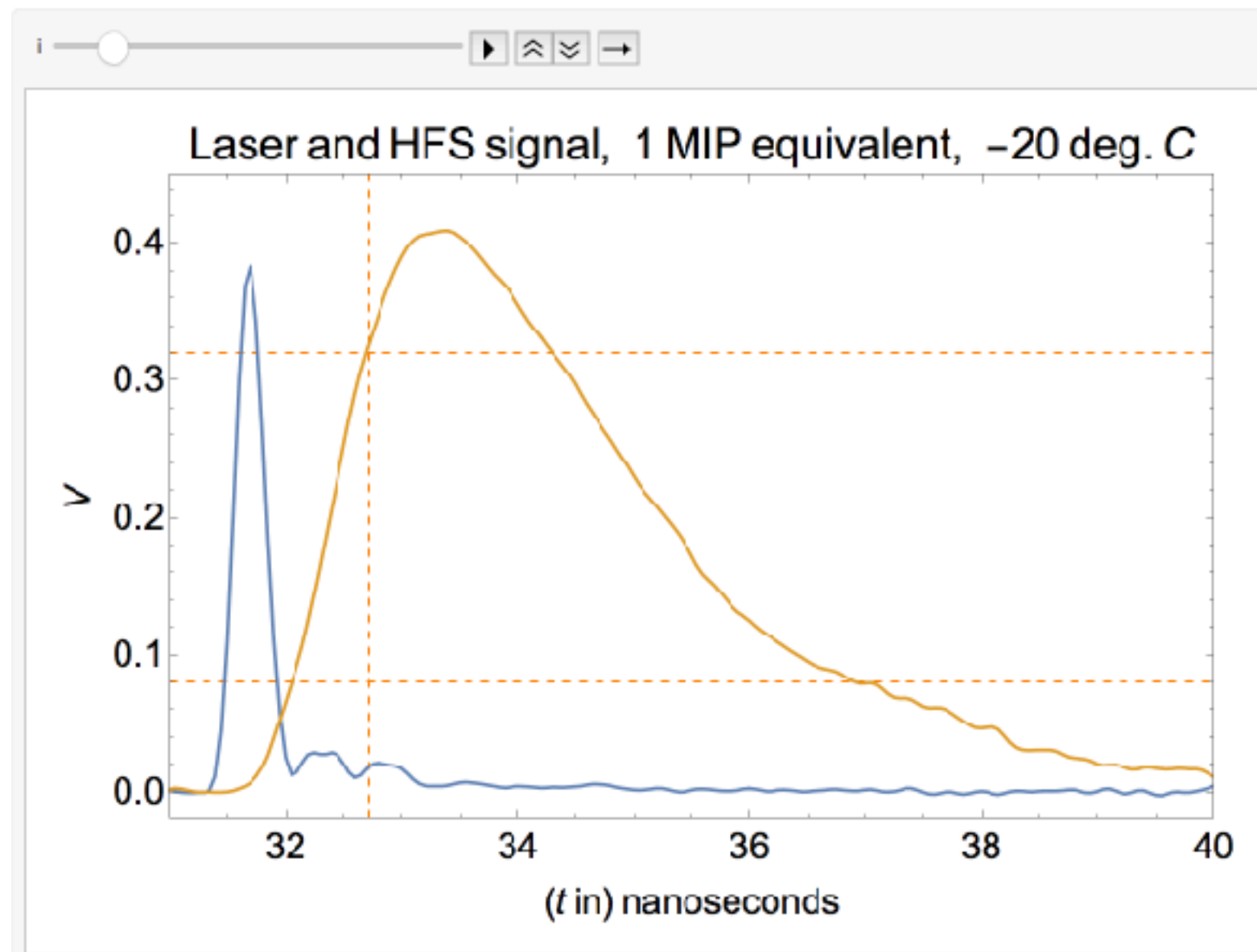
What is best time jitter for 1MIP equiv?

- Eric Delagnes and I tried this w. earlier FEE and SAMPIC see:

D. Breton: Elba 2015

<https://agenda.infn.it/getFile.py/access?contribId=138&sessionId=11&resId=0&materialId=slides&confId=8397>

here we look at data from lab using Mitch's amp



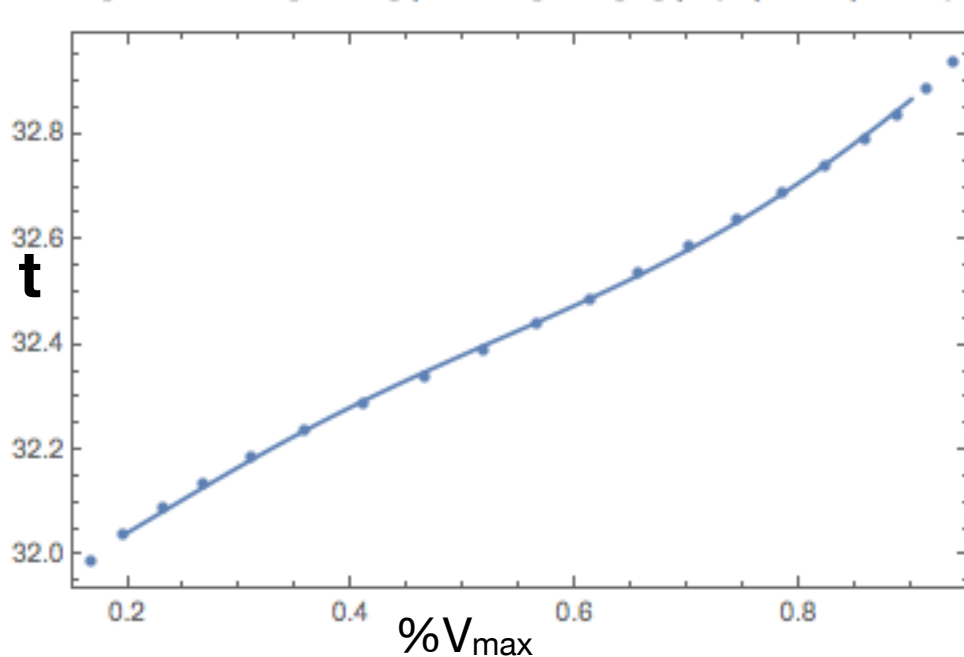
unfiltered baseline
noise ~ 2.2 mV rms
 $\rightarrow \text{SNR} \sim 400/2.2 = 180$.
Risetime = 0.65 ns

naively jitter from noise \rightarrow
 $dt \sim t_R / \text{SNR} = 3.6$ picosec

timing algorithm

- since there is some spread in laser amplitude we typically do simple Constant Fraction timing on the leading edge at ~20%. Other techniques such as filtering (usually Wiener) and fit, signal modeling, etc. all give equiv results for this example.
- here we do a simple power law fit to the full waveform.

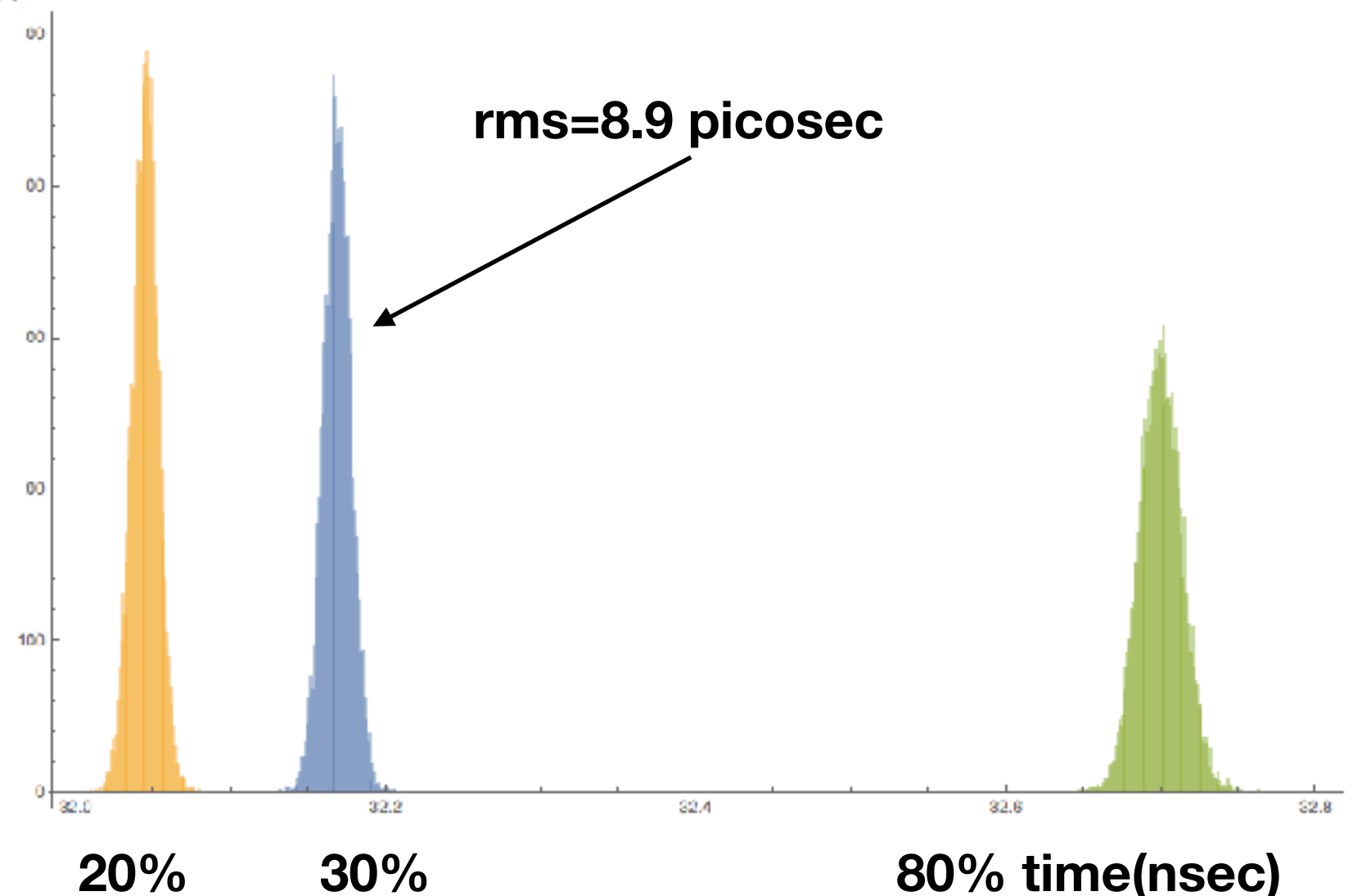
```
Show[ListPlot[data], Plot[nlm[x], {x, 0.2, 0.9}],
```



transposed leading edge

nice result but
contribution from trigger jitter?

no

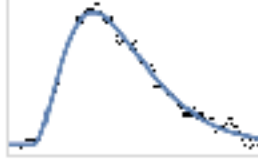
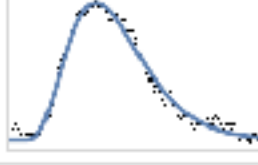
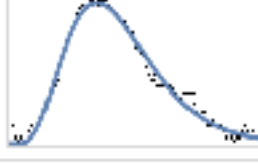
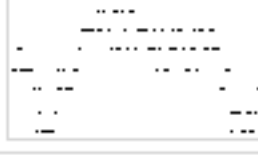
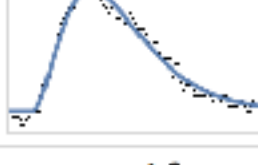
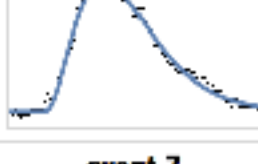
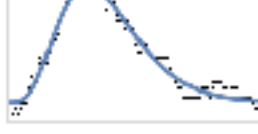


alternative to local Constant fraction fit is signal modeling for which Mathematica has some nice tools

Map function across waves

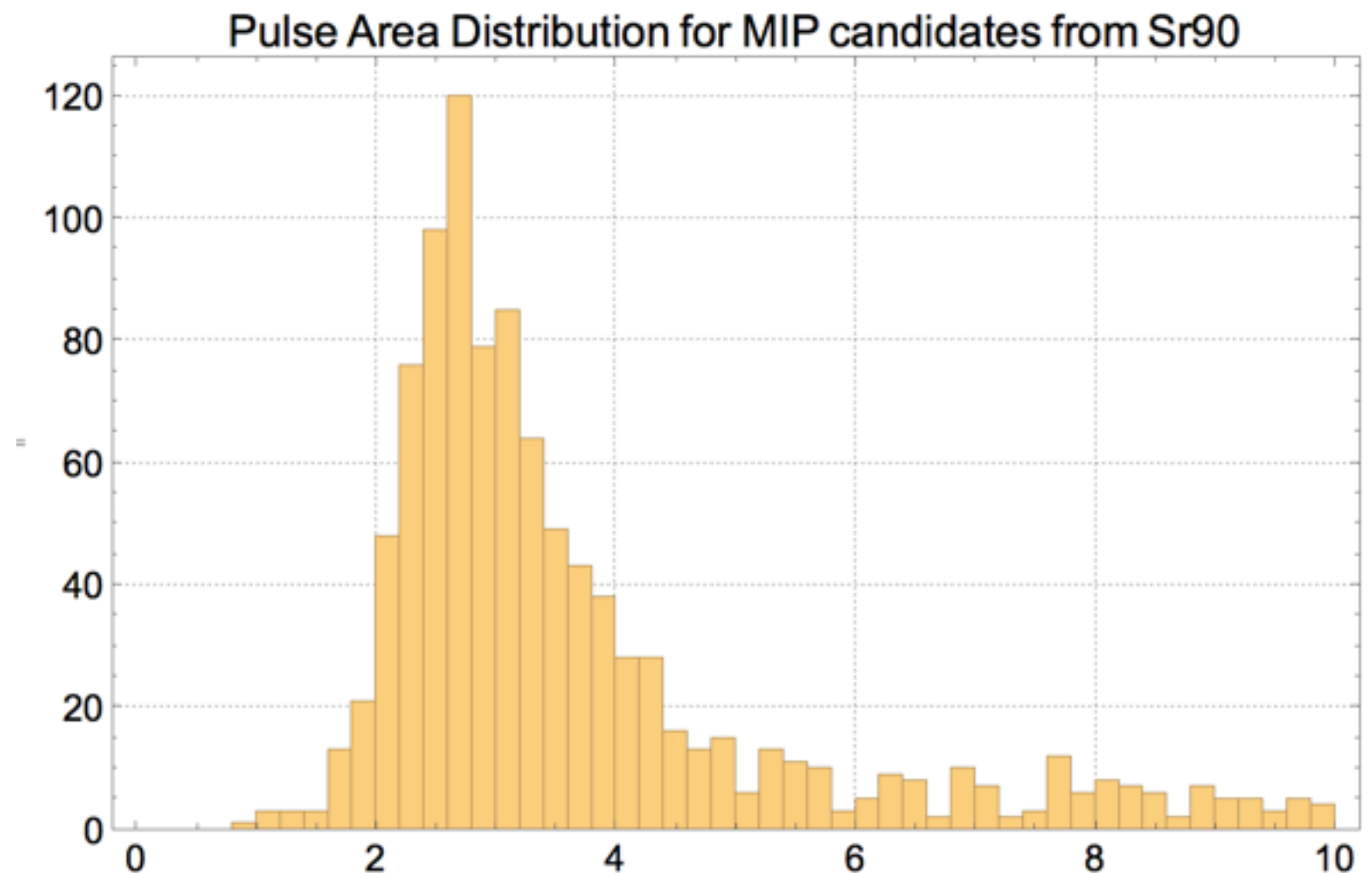
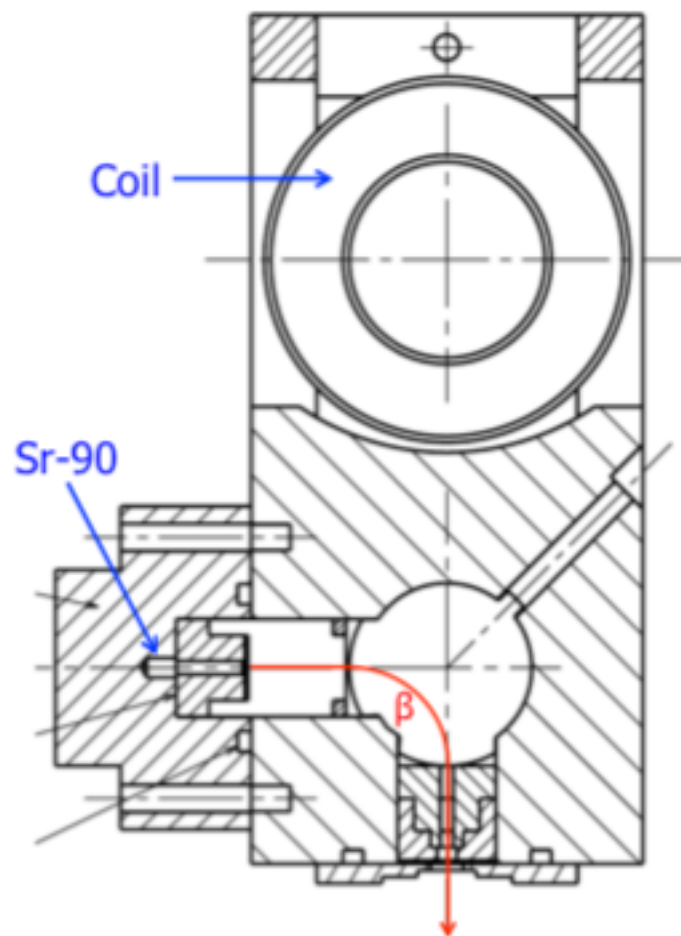
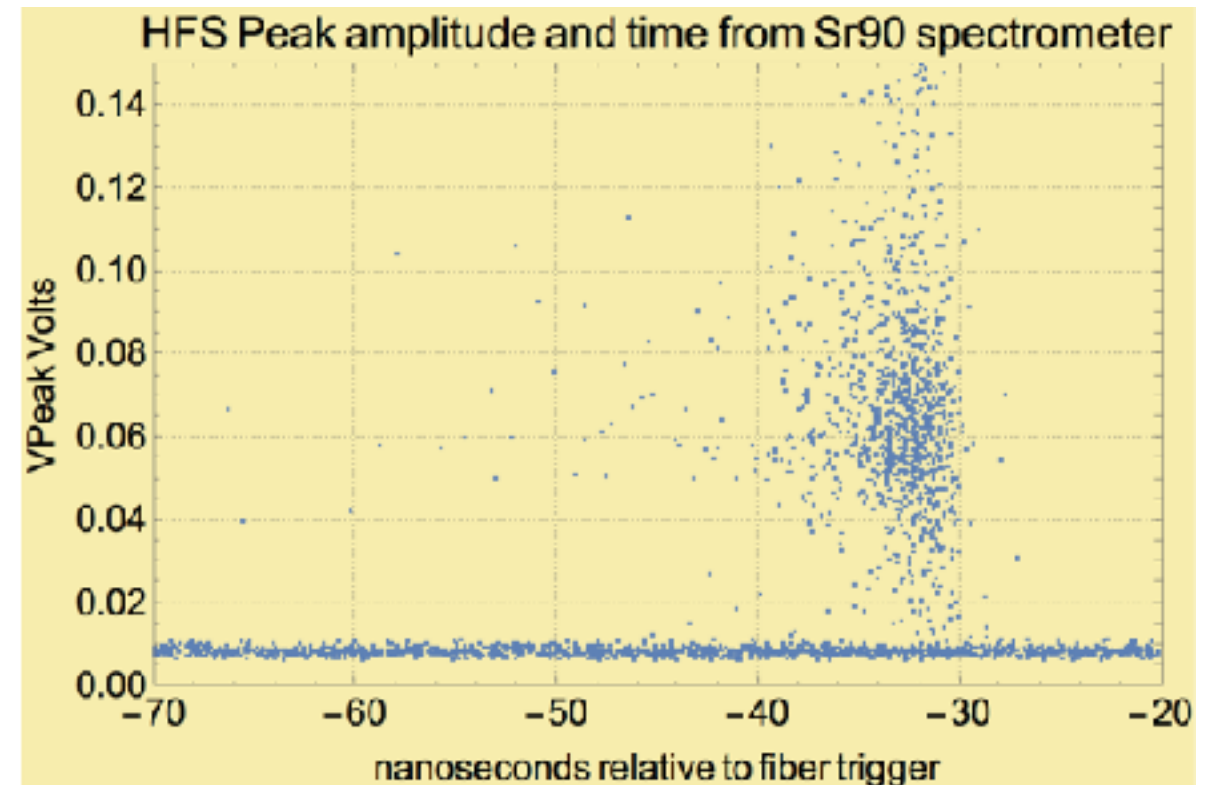
Here I use MapIndexed (this allows me to use the position as an argument). Dataset groups the results together.

```
ds = Dataset[MapIndexed[fit[#1, #2[[1]]] &, wave4[[1 ;; 100]]]
```

event	bestFitParameters	adjustedRSquared	plot
1	{A → 0.119864, n → 2.11306, to → 0.592996, toff → 6.41963}	0.994857	
2	{A → 0.0962981, n → 3.7208, to → 0.401652, toff → 11.3142}	0.992228	
3	{A → 0.11766, n → 3.70992, to → 0.454327, toff → 4.29665}	0.994448	
4	NonlinearModelFit::sszero	—	
5	{A → 0.0926168, n → 2.05265, to → 0.595536, toff → 7.40185}	0.991077	
6	{A → 0.11257, n → 2.50197, to → 0.506459, toff → 17.7226}	0.9939	
7	{A → 0.0667517, n → 4.39367, to → 0.377799, toff → 27.448}	0.986334	

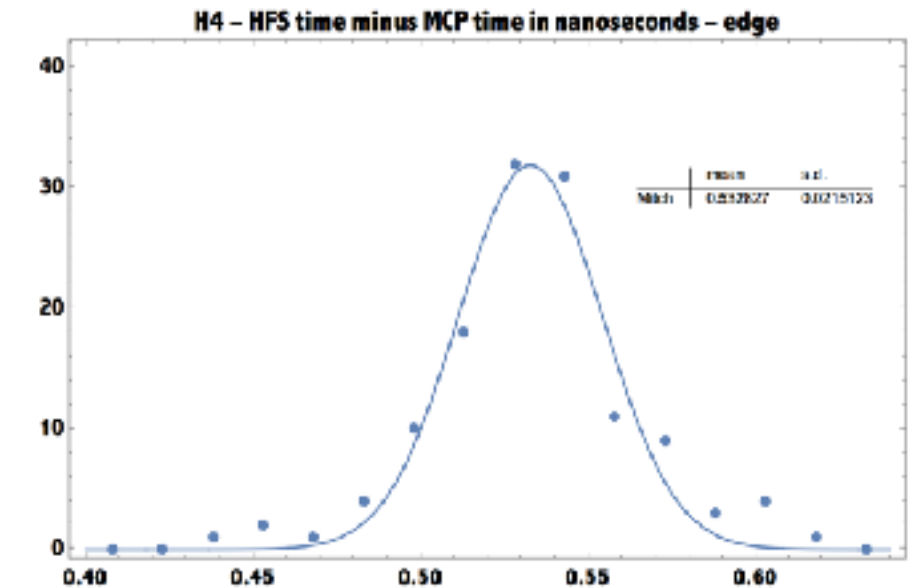
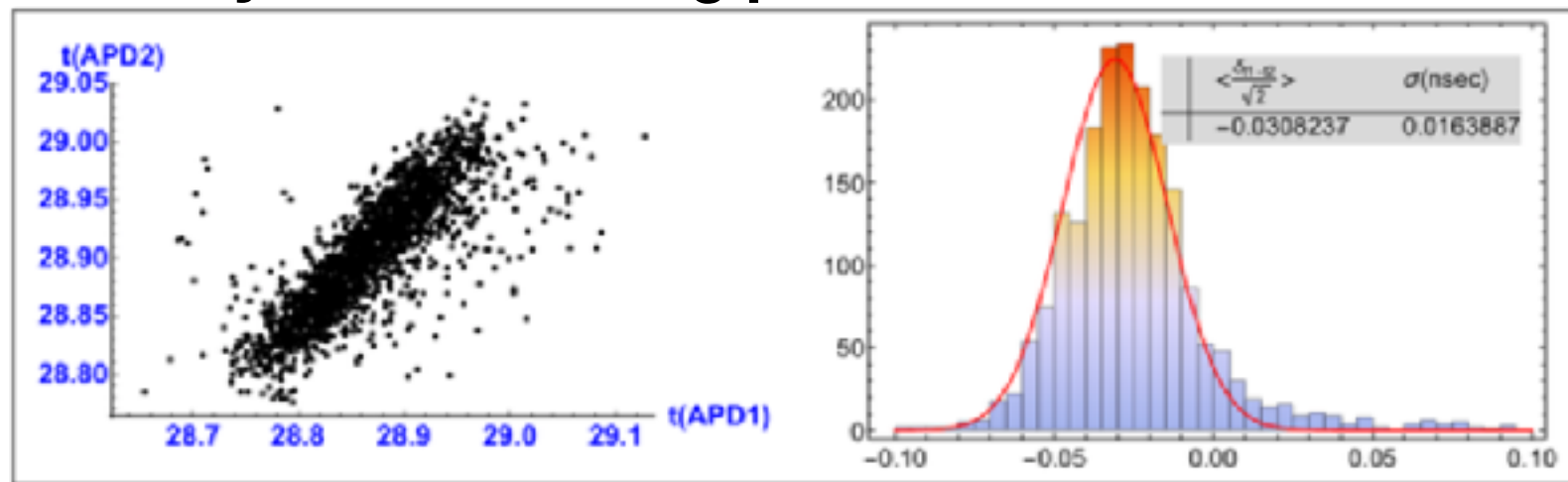
an alternative to HE beam

small device (~6")
~1 Amp drive current
selects to +/-10% 1 MeV electrons
Argonne made similar in
SSC era, fell into disuse

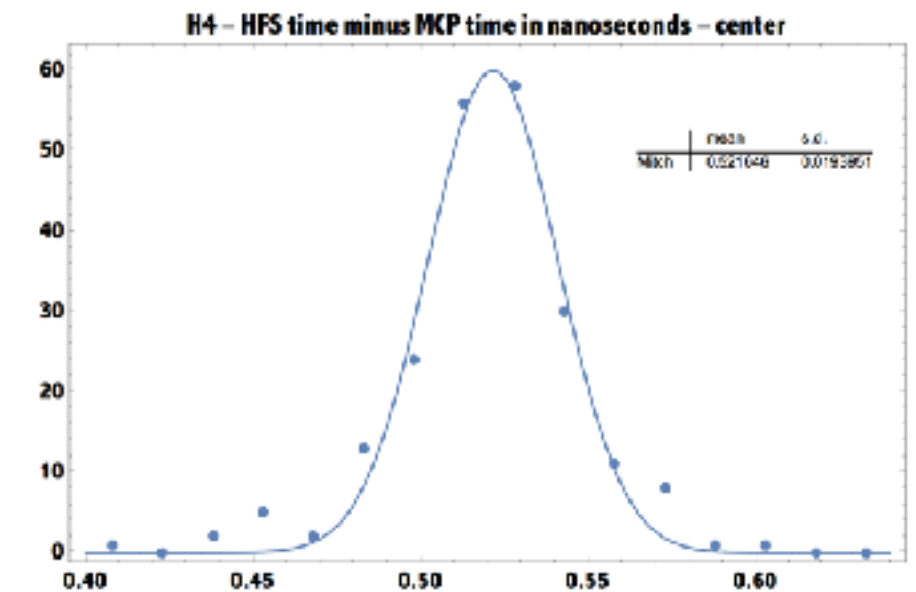
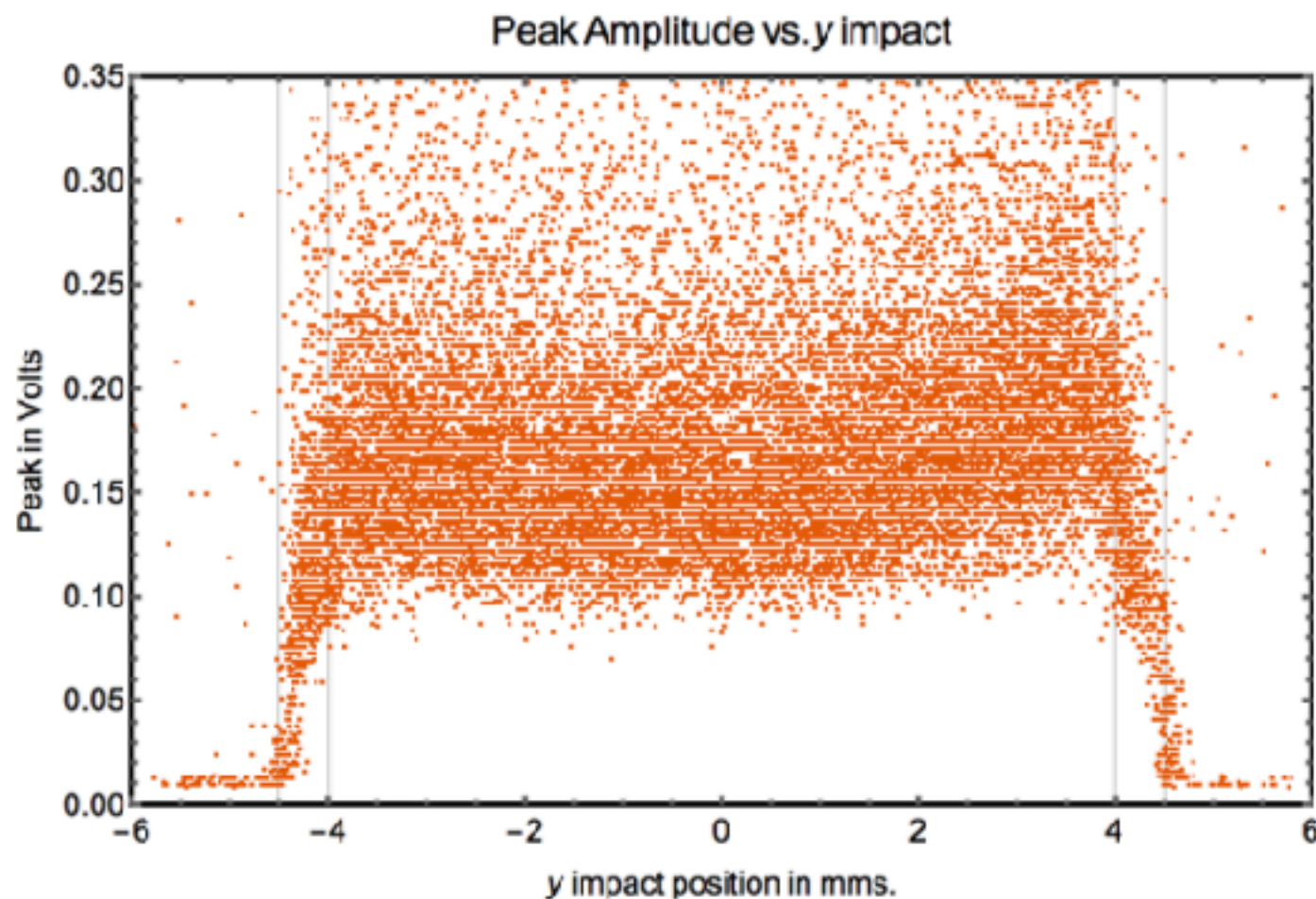


Some test beam results from 2016-17

early result showing promise of HFS



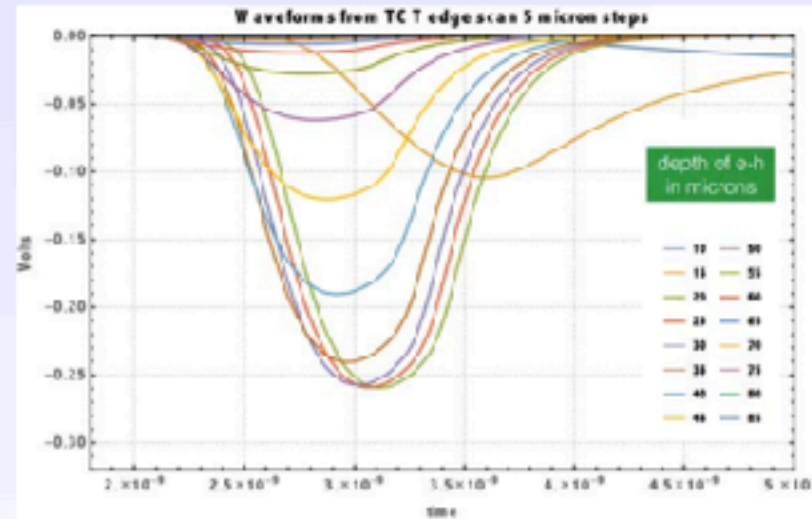
2016: Nice Amplitude Uniformity over 64 mm² pixel



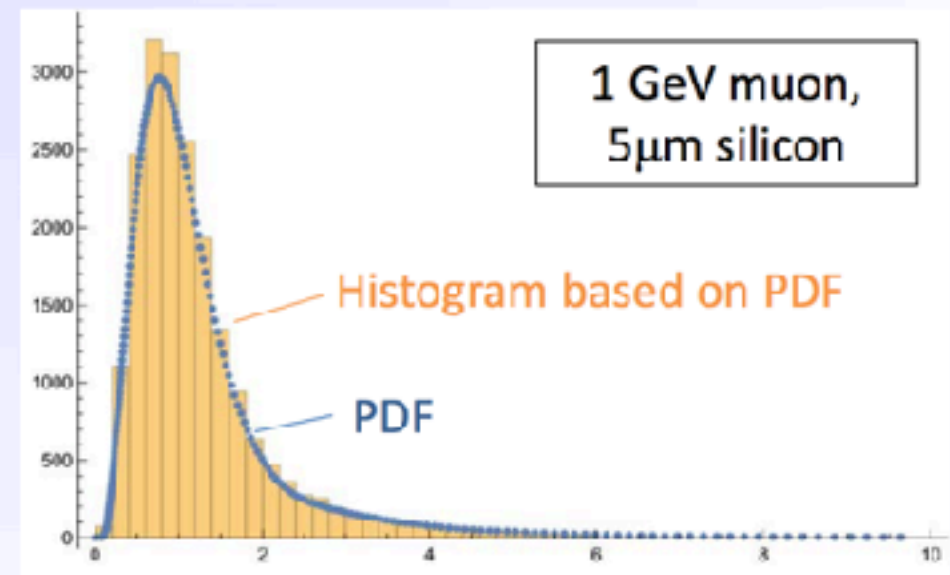
similar time res. at edge & center
however 10-20 picos time walk
-> attributed to packaging/interconnect
goal of 2017 to eliminate walk

SILVACO used to model radiation damage & Landau Contribution to Timing

M. Moll, RD50 mtg.
June 2016



Voltage: 1800 V
16 positions (16 slices)



1 GeV muon,
5 μ m silicon

Histogram based on PDF

PDF

Deposited Charge
[KeV/5 μ m silicon]

[PDF provided by Su Dong, Stanford, USA]

Meanwhile, Packaging
evolution

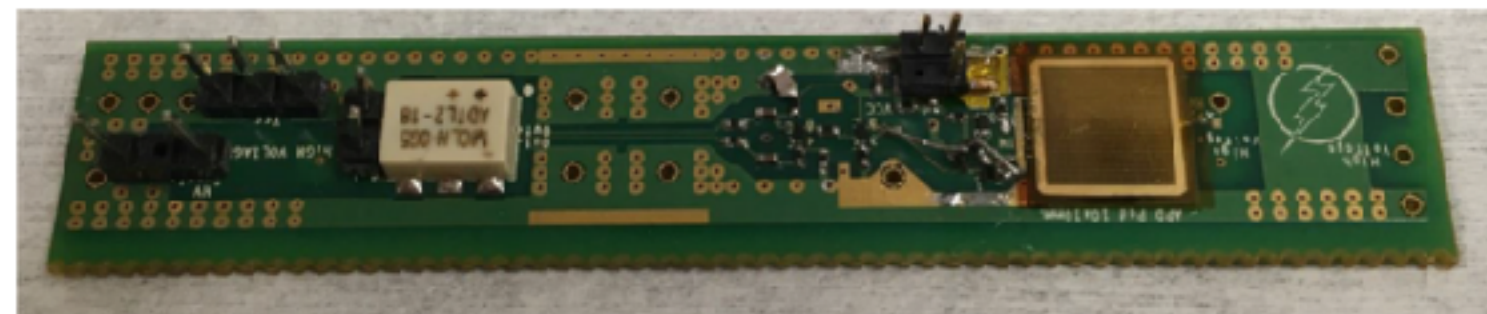


Figure 10. A photograph of a 1st generation PCB with a mounted mesh APD seen on the right-hand side of the PCB.

Packaging by Bert Harrop, Princeton
discrete TIA from U. Penn.(M.Newcomer)

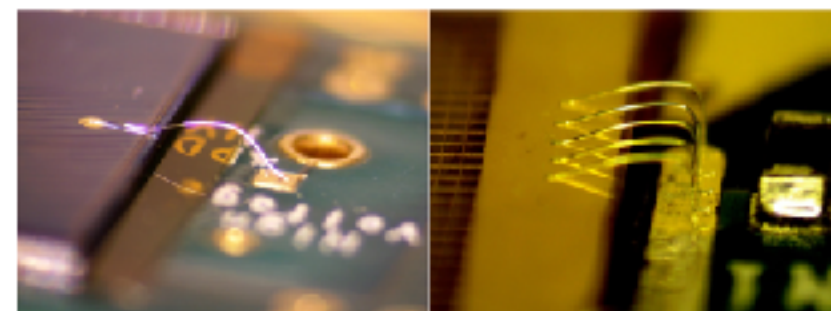
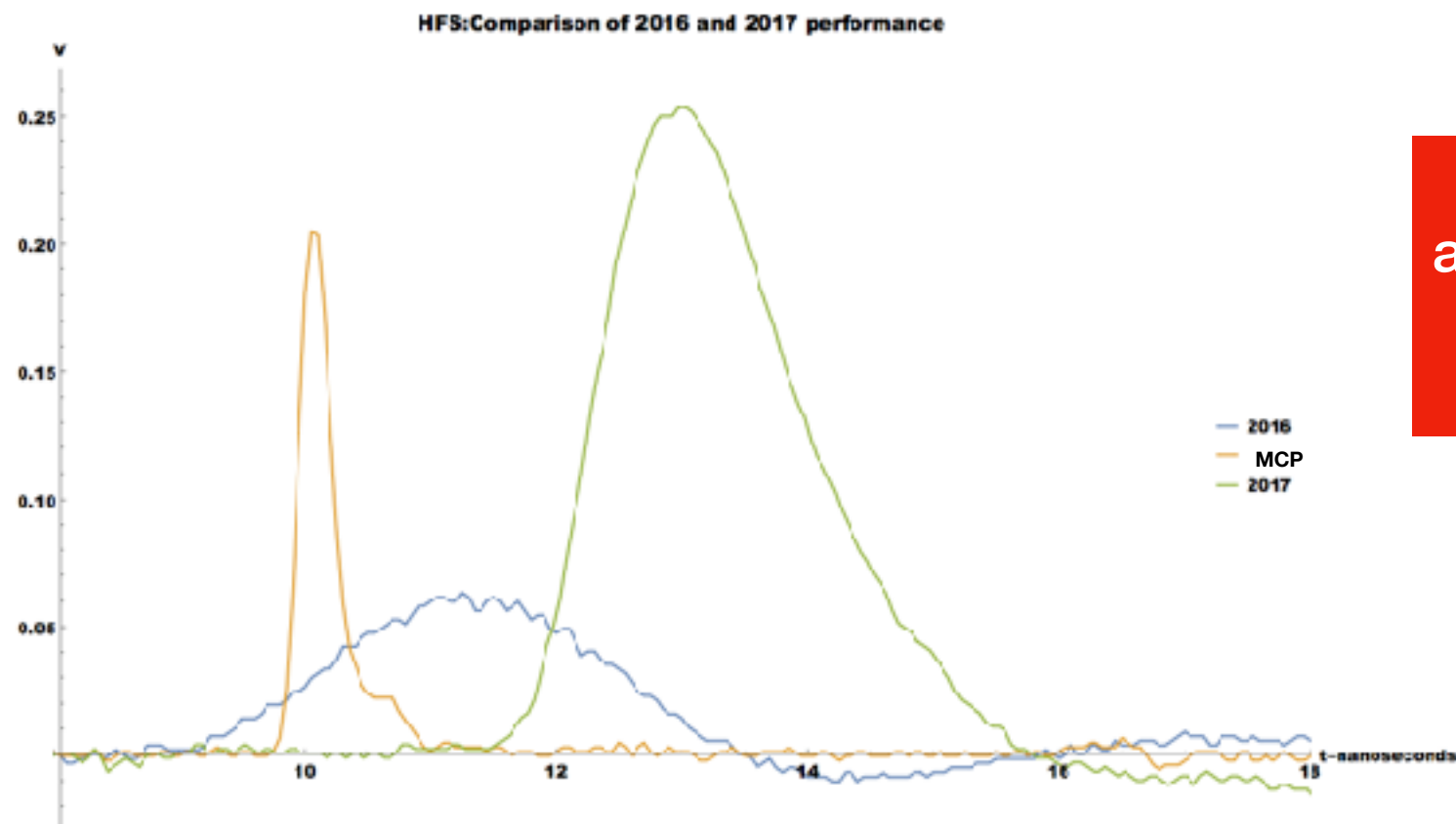
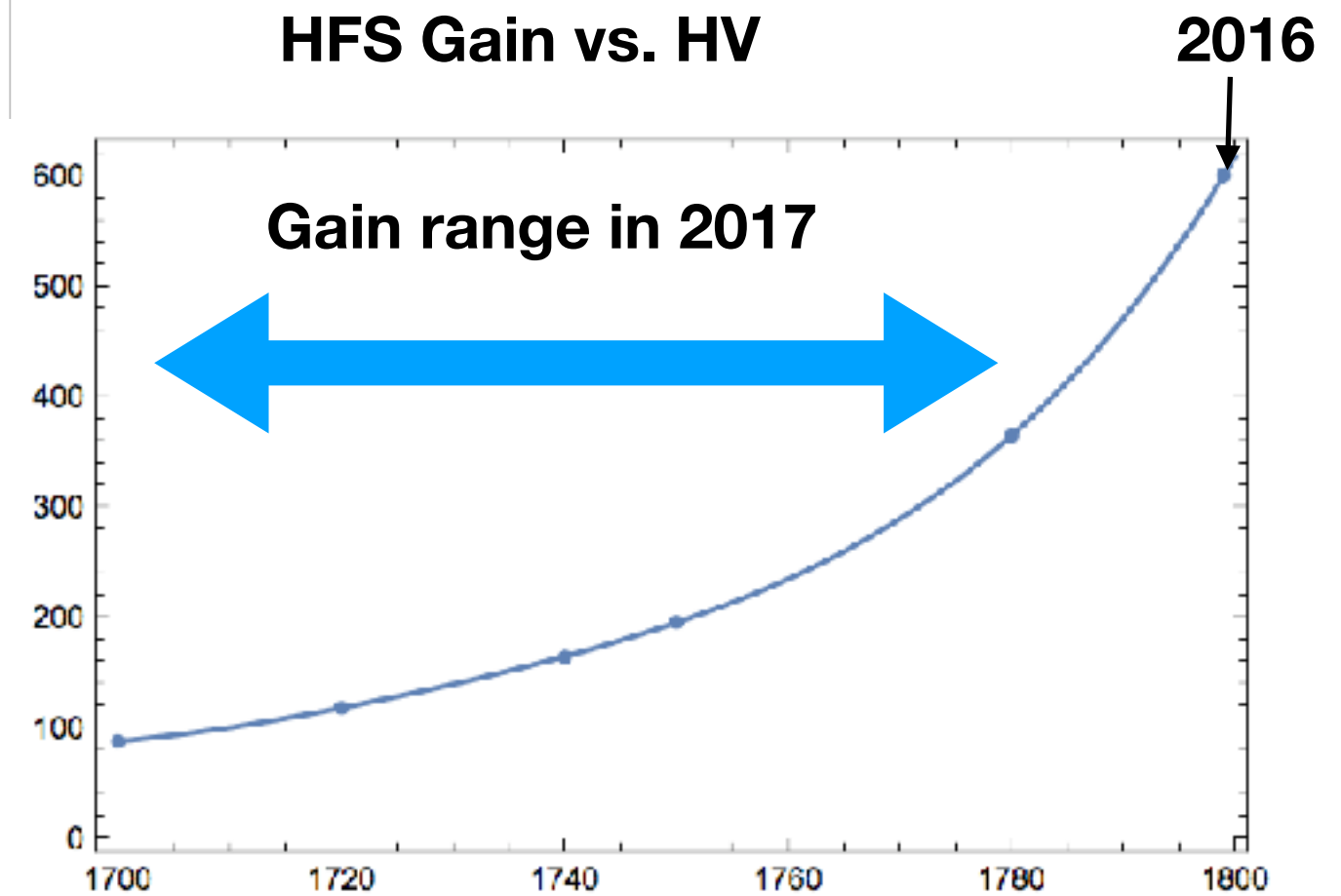
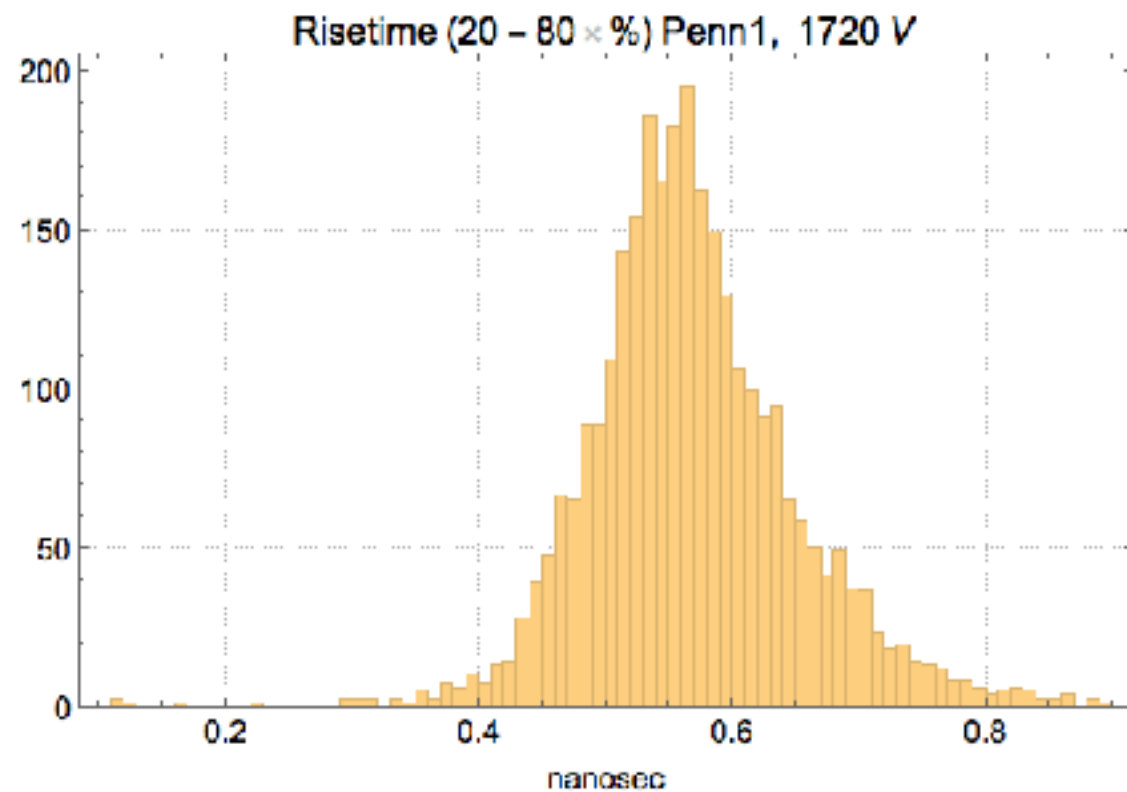


Figure 11. (Left) A close up photograph showing the wire bonded APD anode. (Right) A close up photograph showing the wire bonded Ni mesh screen.

2017,2018 (150 GeV muons)=> improved speed from FEE Integration

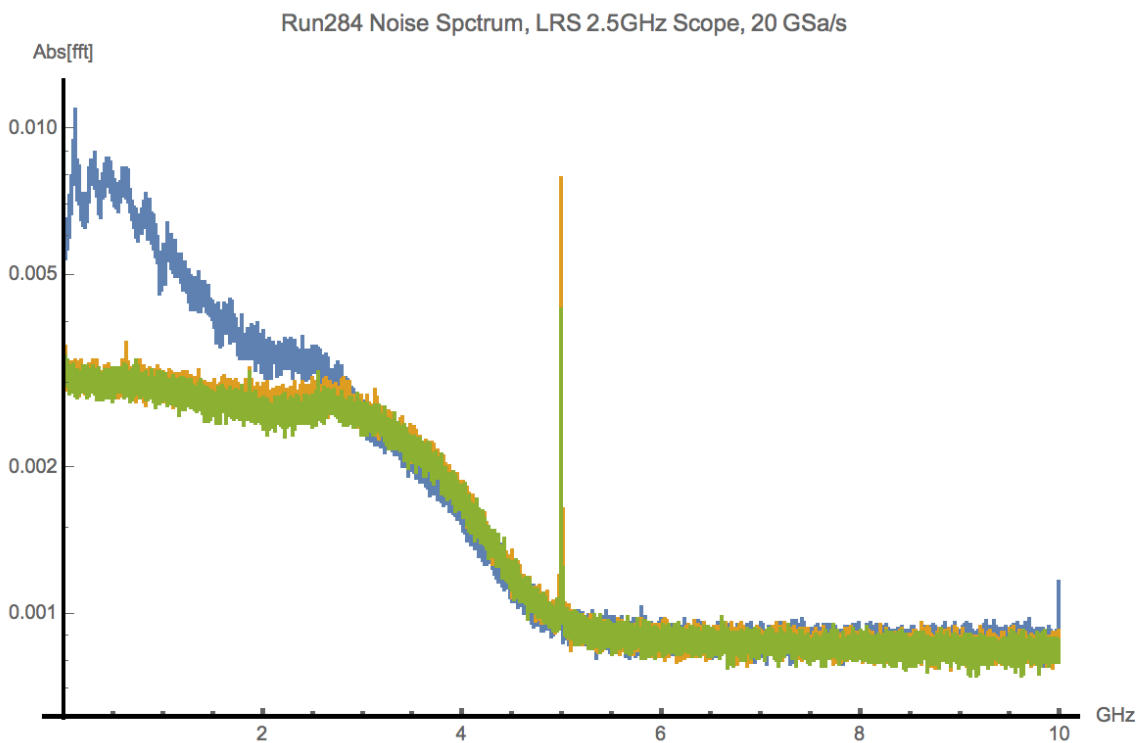


with improved integration
and constant iterations in Penn design
see real impact on signal quality
thank you Mitch & Bert!

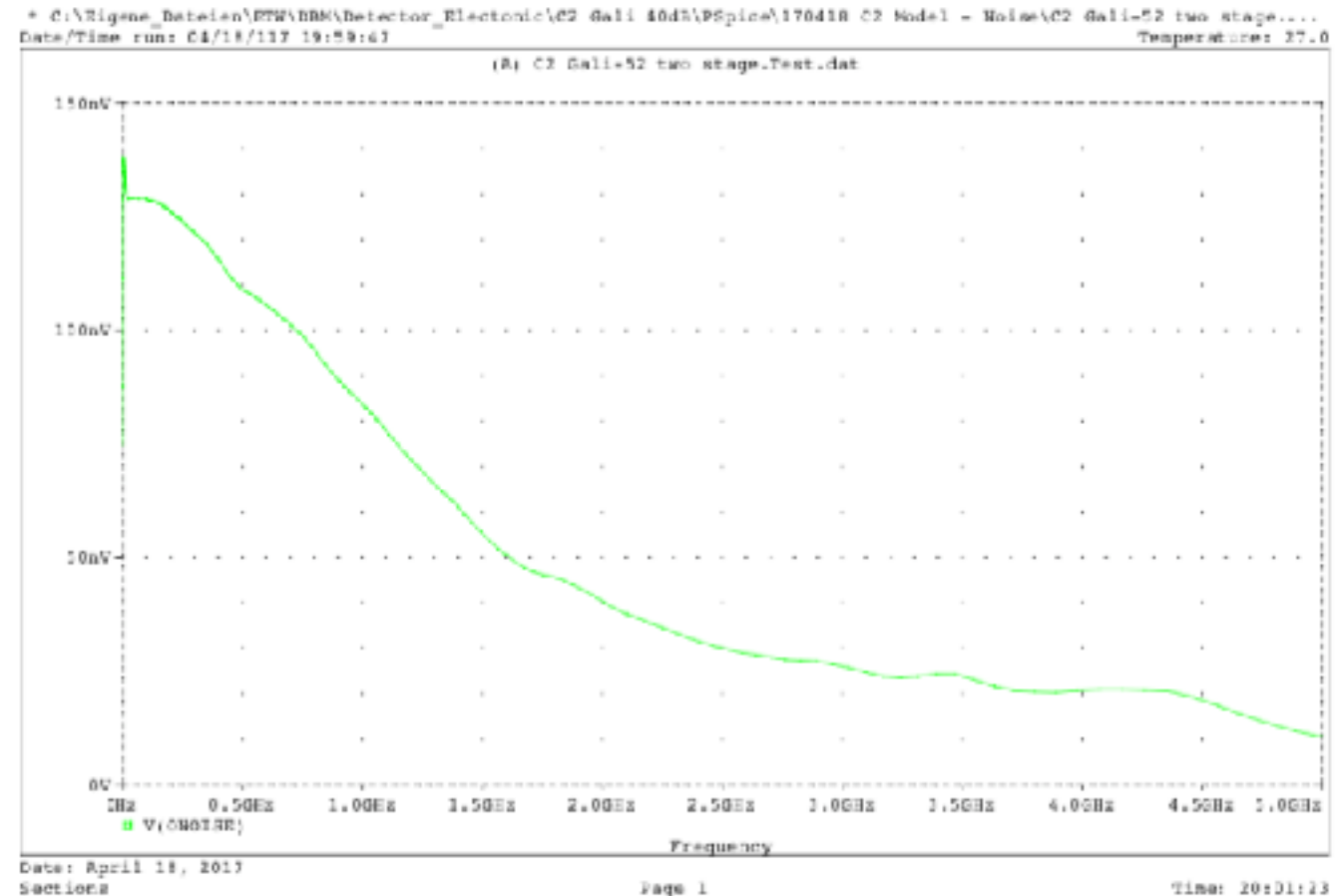
Mitch N's ASIC (funded by US/CMS)
also back from MOSIS
first look in Aug '18 beam

Discrete Fourier Transform

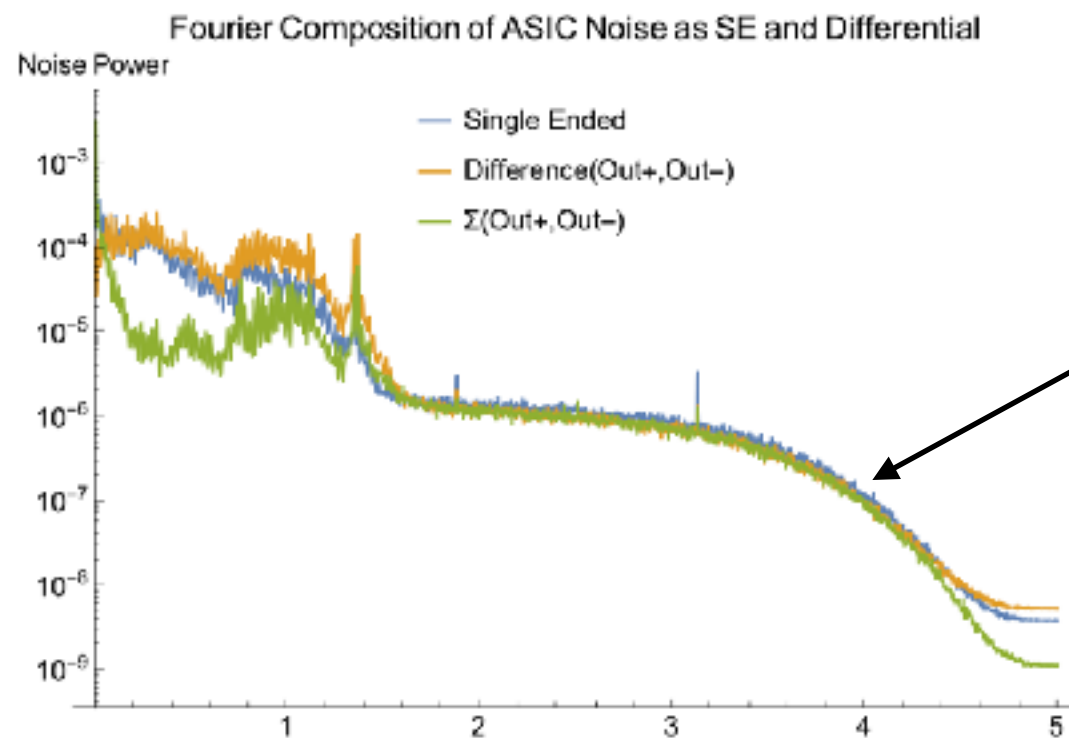
-useful language to correspond w FEE designers



our test beam noise spectrum



confirmed by E. Griesmayer(Cividec)- SPICE

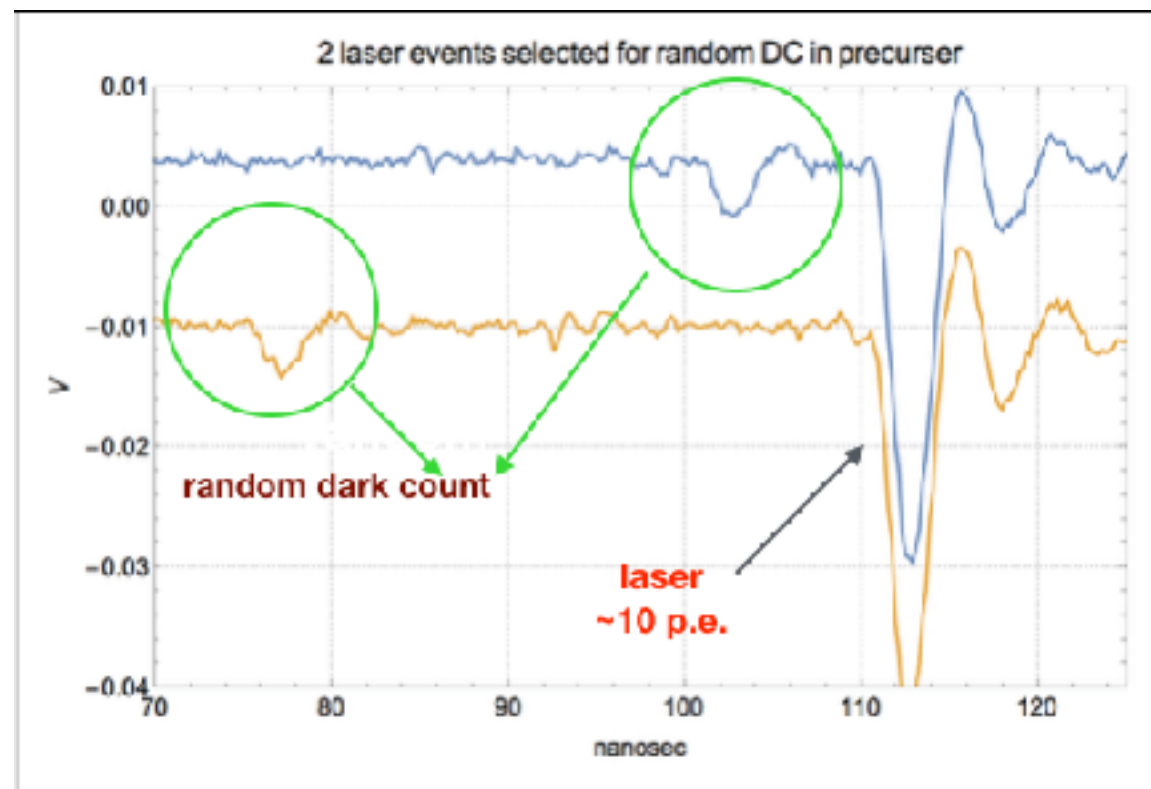


first testbeam exposure of
HFSilicon w Mitch Newcomer's
new ASIC Aug.2018

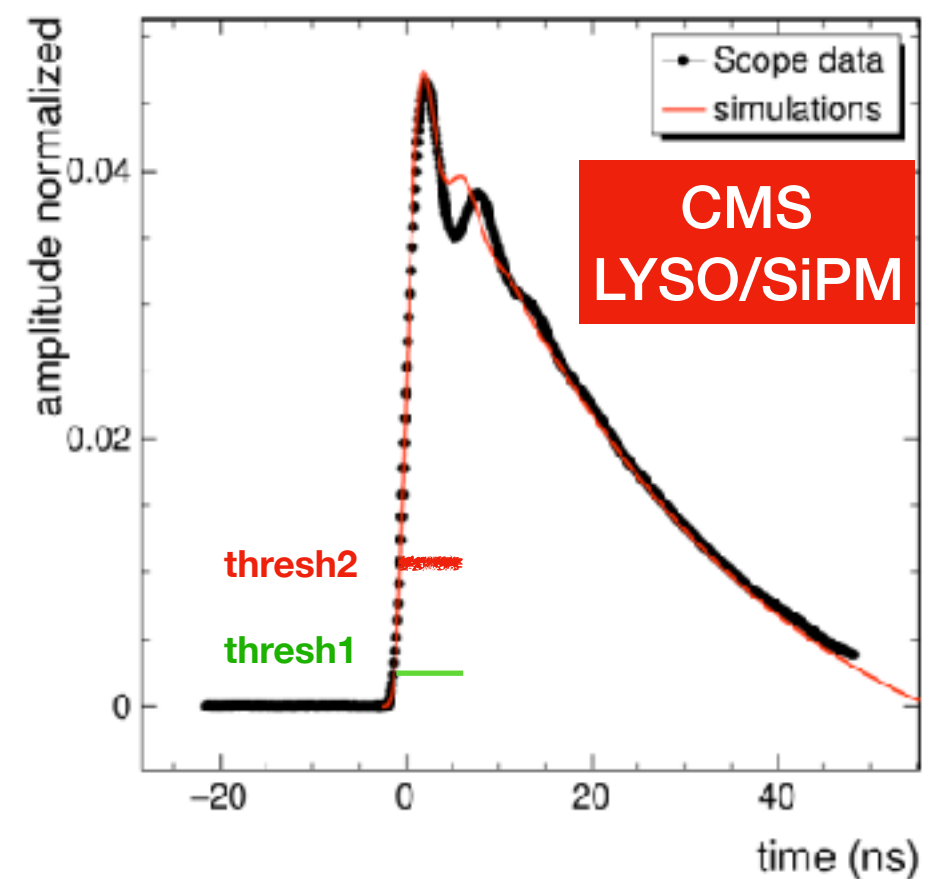
Useful interaction on architecture for CMS Readout (LIP,CERN, U. Virginia)

“end of life” $\times 10^5$ increase in Dark counts
a challenge for CMS baseline subtraction

-> collaborate w LIP design team using laser
and dc waveforms to validate
simulations



could 2 threshold tdc replace
1 threshold + pulse area in CMS Barrel?
“yes, maybe better”-A.Ledovskoy, U.Va.



similar questions in other fields:

ACCEPTED MANUSCRIPT

A 100-ps Multi-Time over Threshold data acquisition system for cosmic
ray detection

some conclusions:

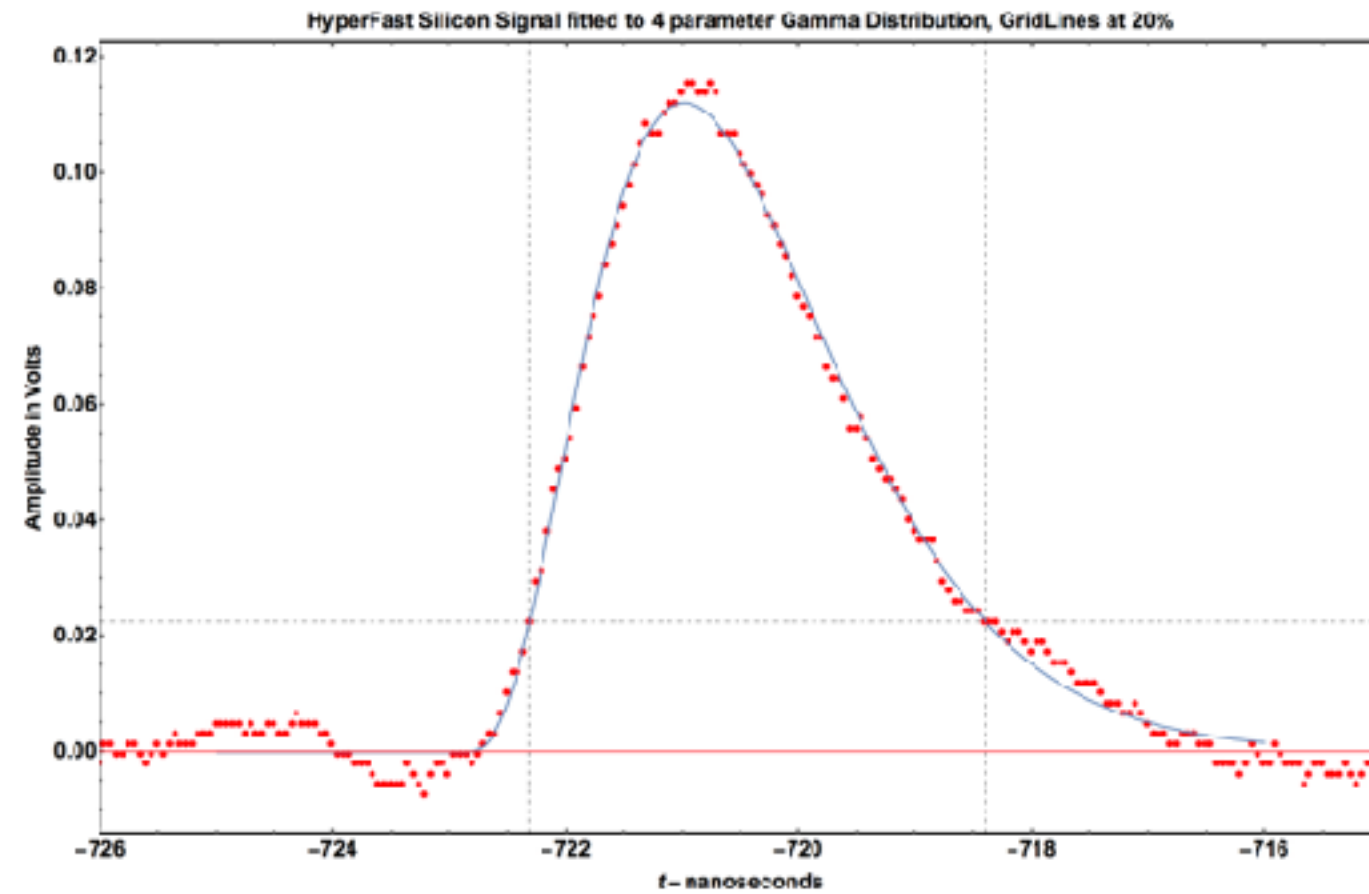
- we are in an interesting domain where detector physics rather than electronics (SNR, rise time) govern resolution
- the principle technology choices of the LHC upgrades are based on Silicon with internal gain
- unlike the case with gas detectors, the fundamental timing limitations not fully modeled.-> well worth pursuing
- at the same time there is a real opportunity to use a combination of modeling and machine learning on a large data set to further develop signal processing algorithms. Subject of a current proposal with Wolfram Research.

thanks for your attention!

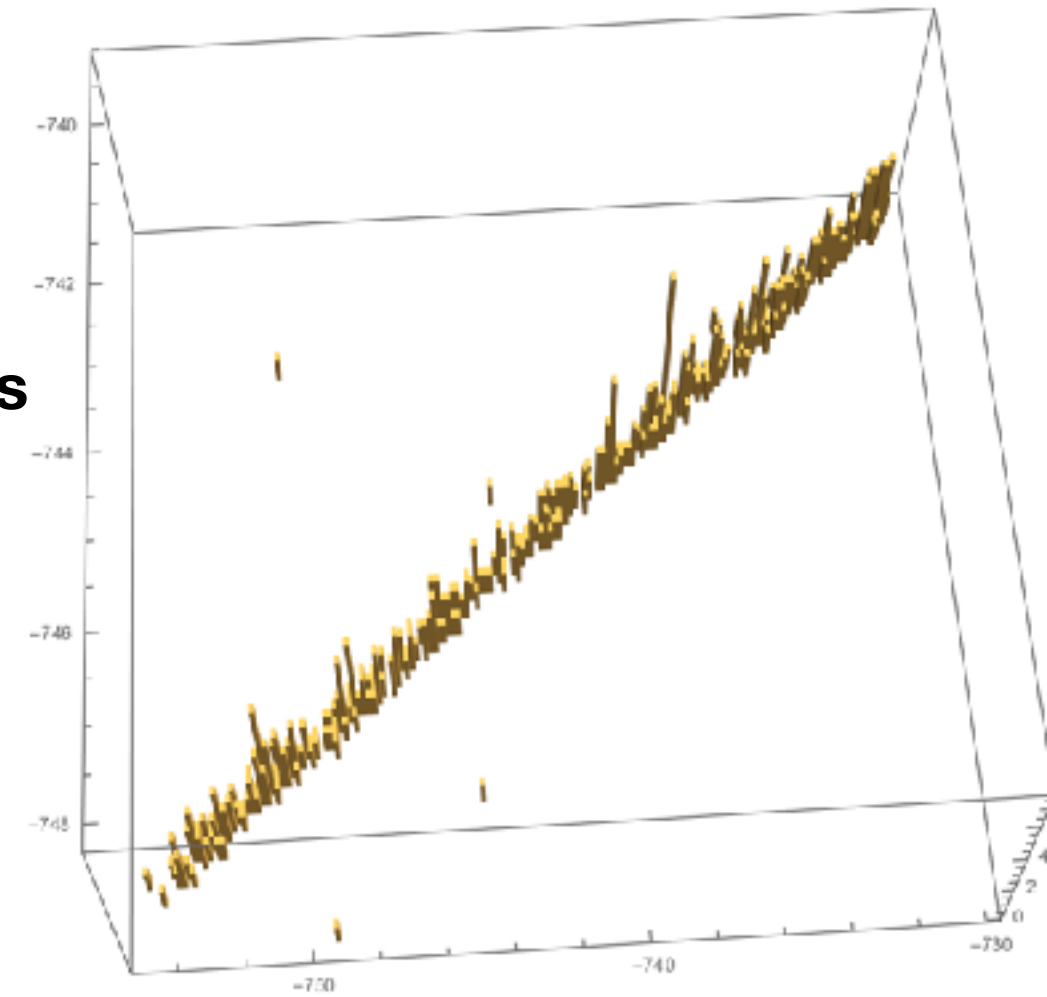
BACKUP

2017 beam Campaigns within PICOSEC infrastructure (cont)

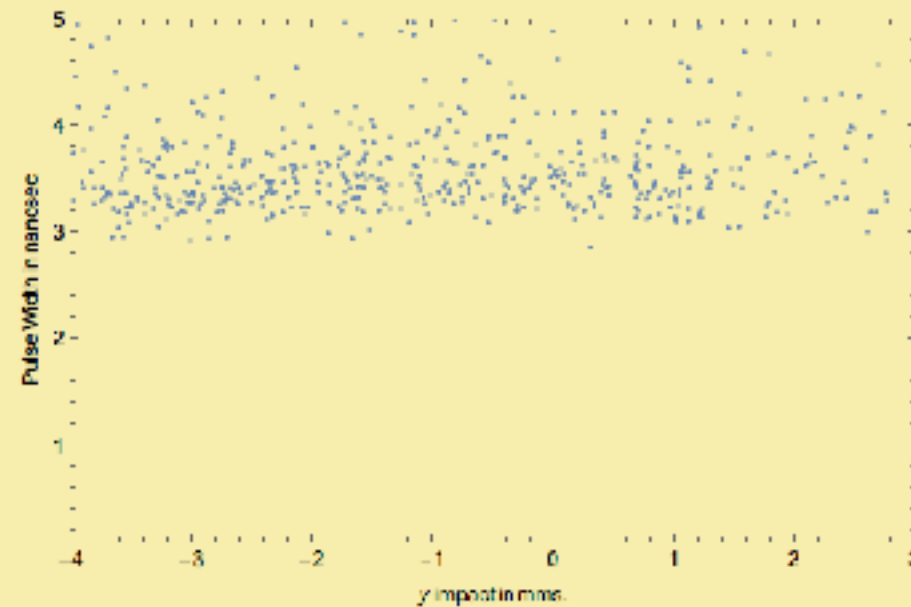
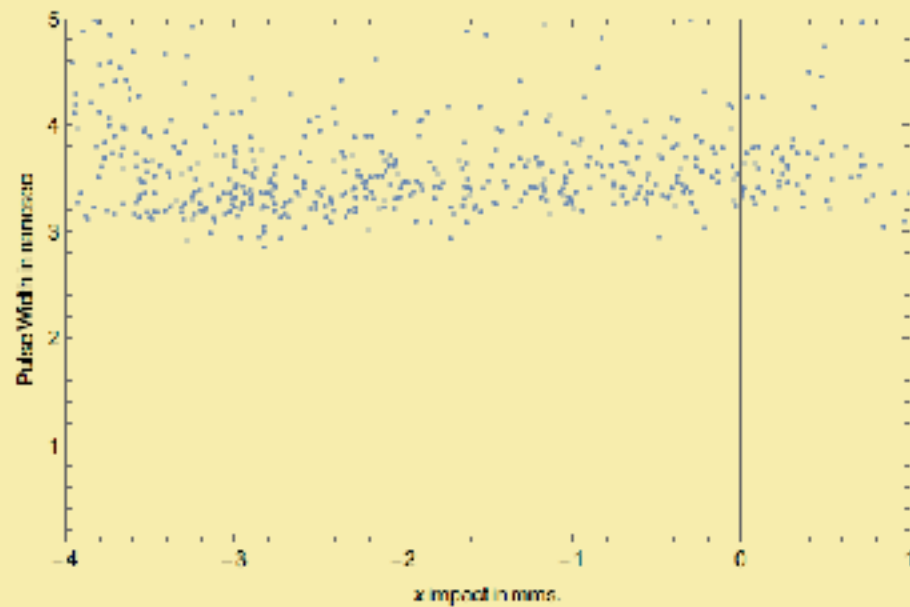
Signal modeling useful to probe position dependence



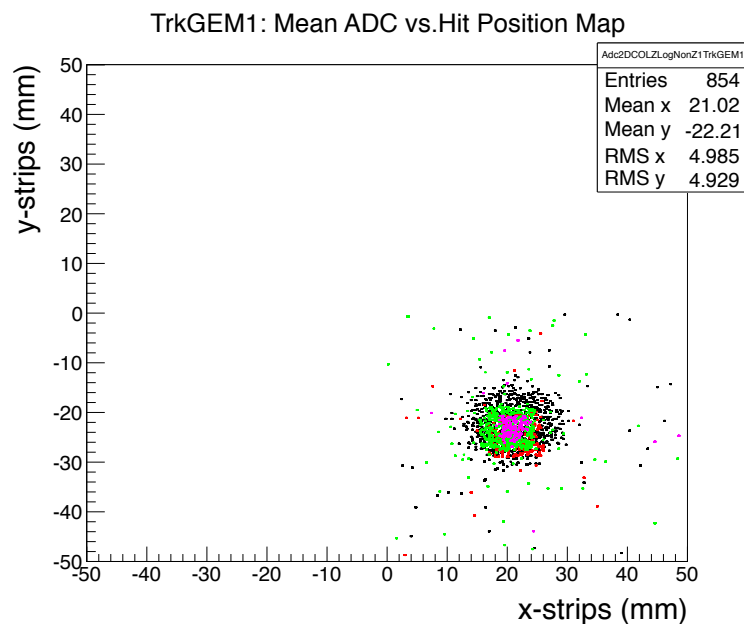
hfs



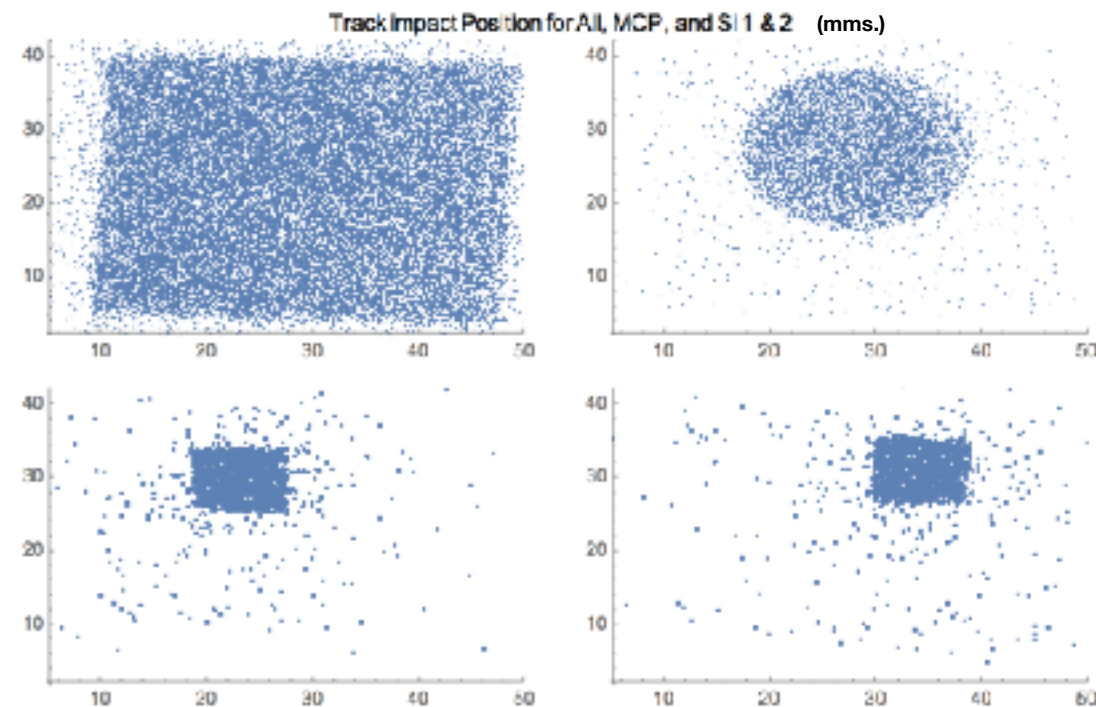
HFS Pulse Width vs. Track Impact in x and y



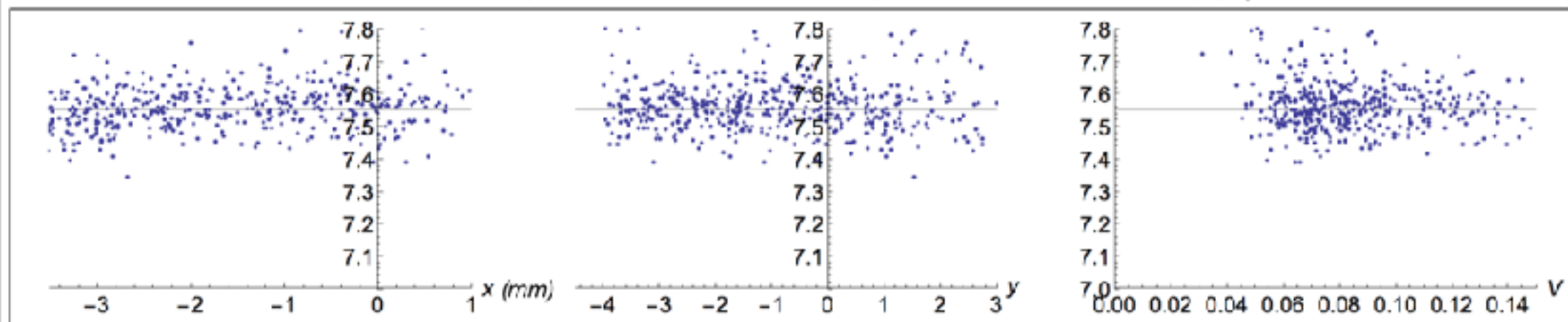
mcp



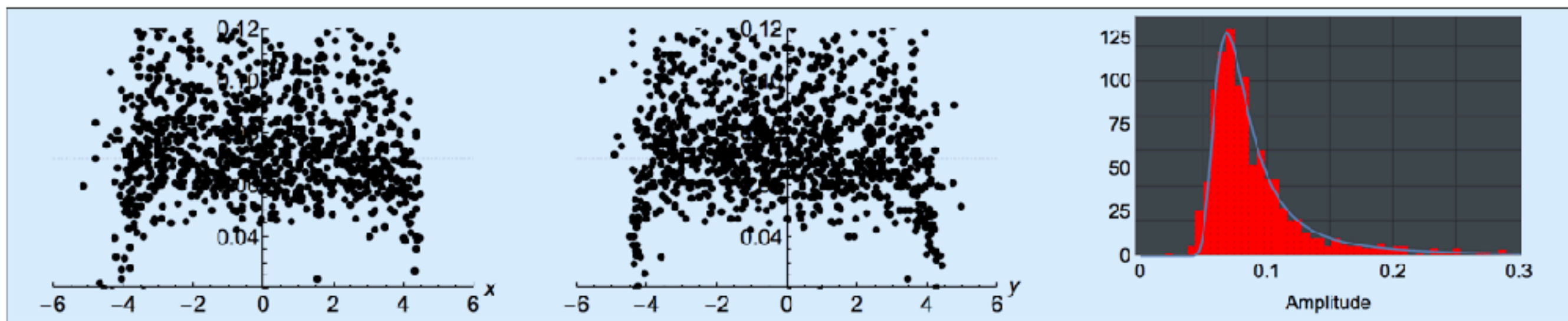
<—small area, aligned
large area trigger->



HFS (Penn2) – MCP time vs. x impact, y impact and Amplitude (V) -(*nanosec vertical scale*)

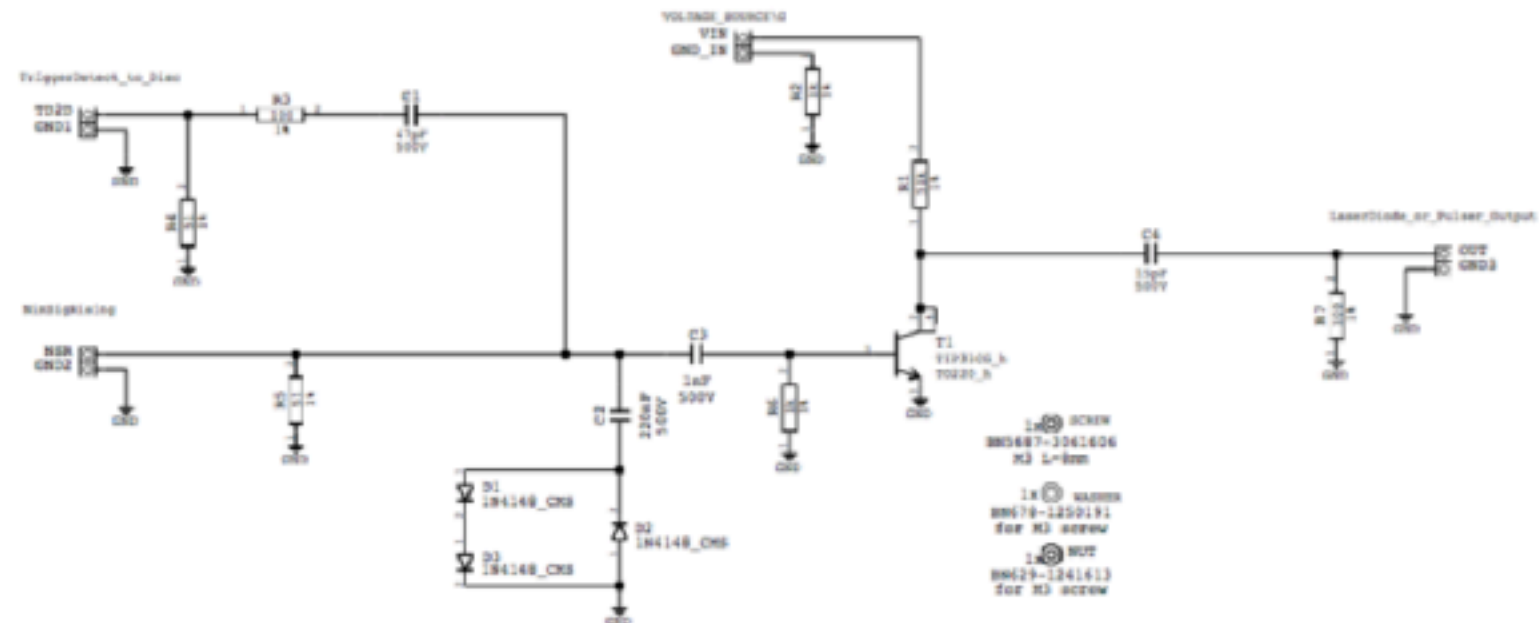
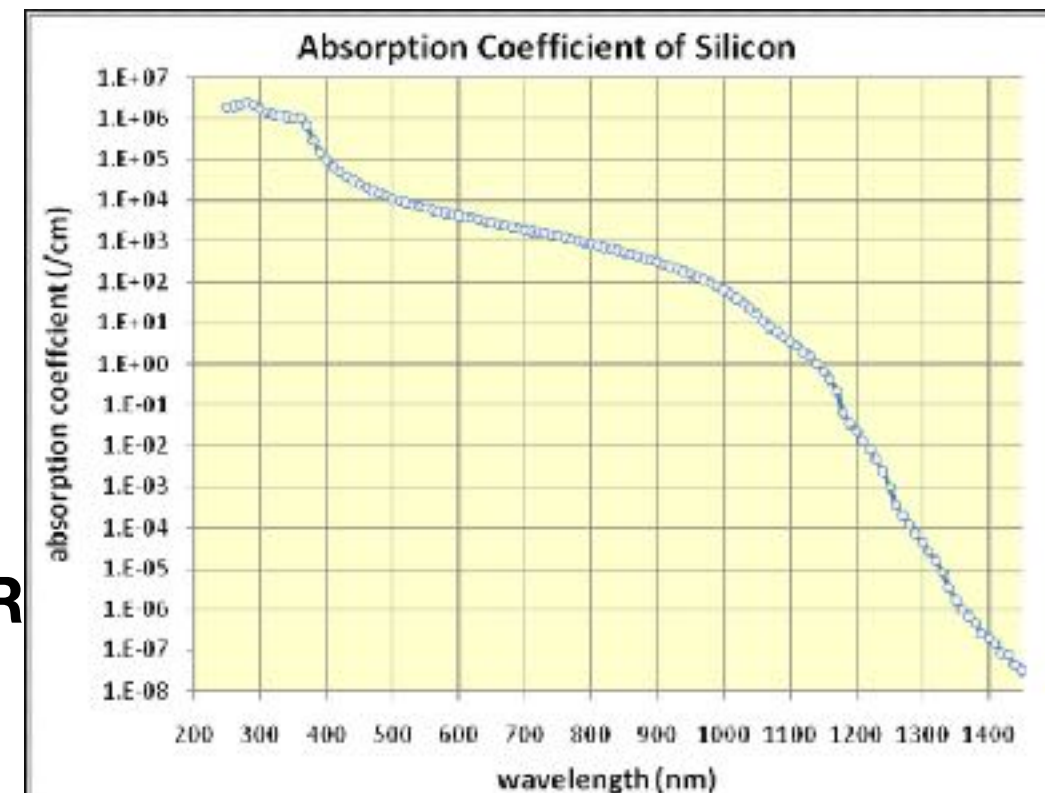


HFS Penn2 Peak vs.x ----- and Peak vs.y and ----- Full Landau Distribution



a tour of HFS laser

- Laser characterization was useful for developing capacitive(mesh) readout, etc.
- it provides a baseline performance, free of time jitter due to Landau/Vavilov
- Goal is to make a laser pulse that deposits same average charge profile as a MIP
- few 10's of micron Si pretty transparent~ 1000nm IR
- we use typically 980nm or 1060nm

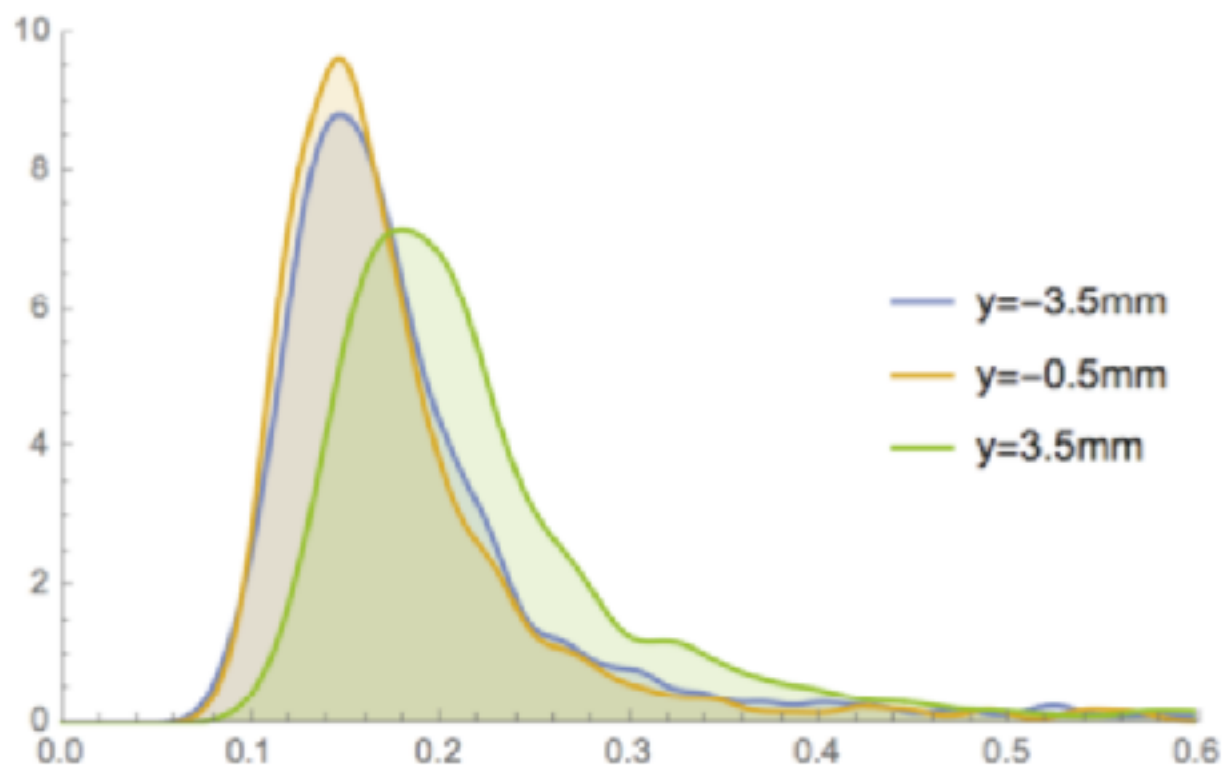


few 100 picosec laser drivers typically pricey so Mitch Newcomer and I developed a cheap one "Instapulser CMS"

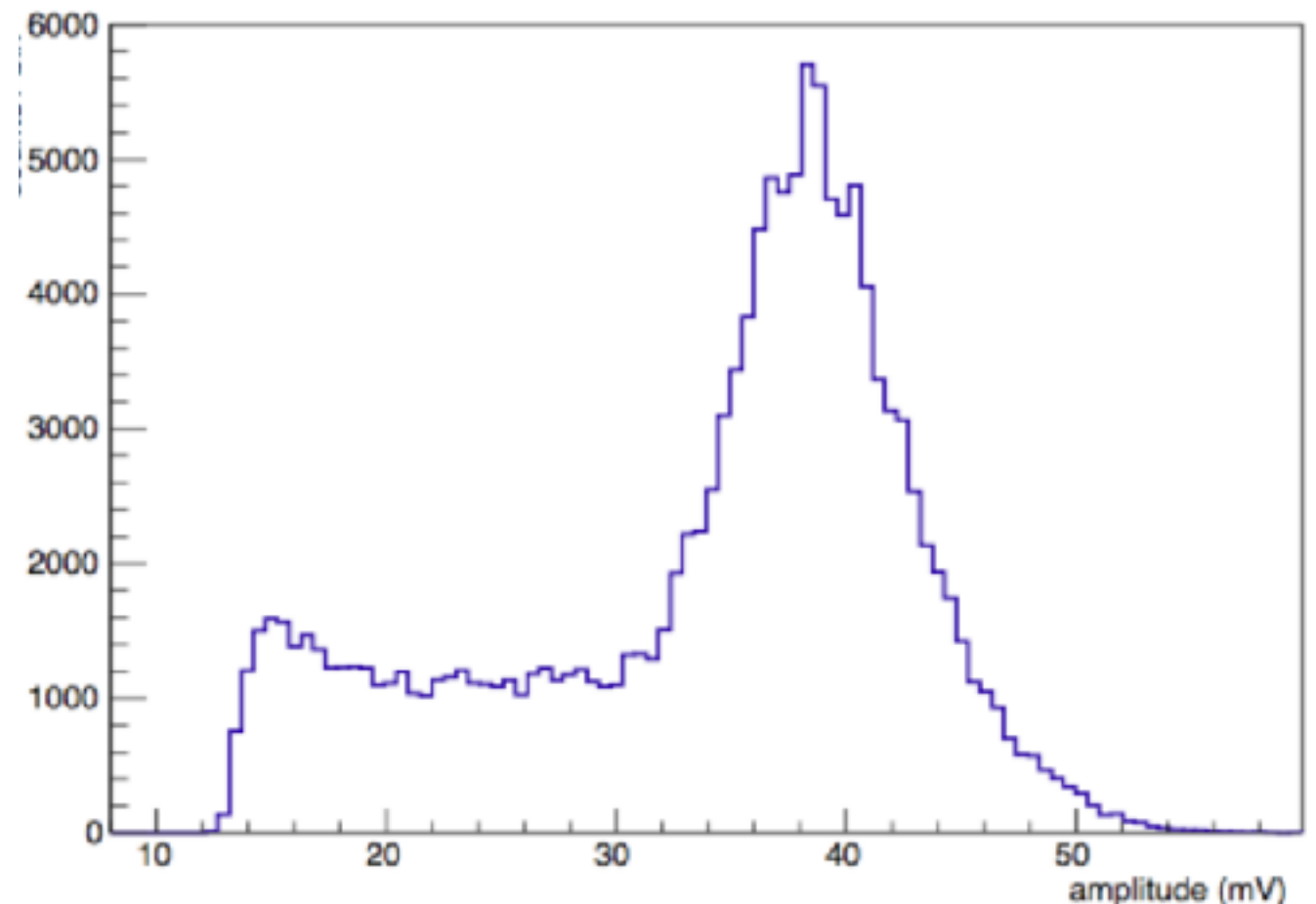
Laser Pulse Intensity

- rather than dead-reckoning (ie calculating e-h pairs/micron and gain elements) we compare, in situ, HE beam response to a stable reference (ie Fe55 X-ray source). Also nice momentum selected 1MeV electron source.

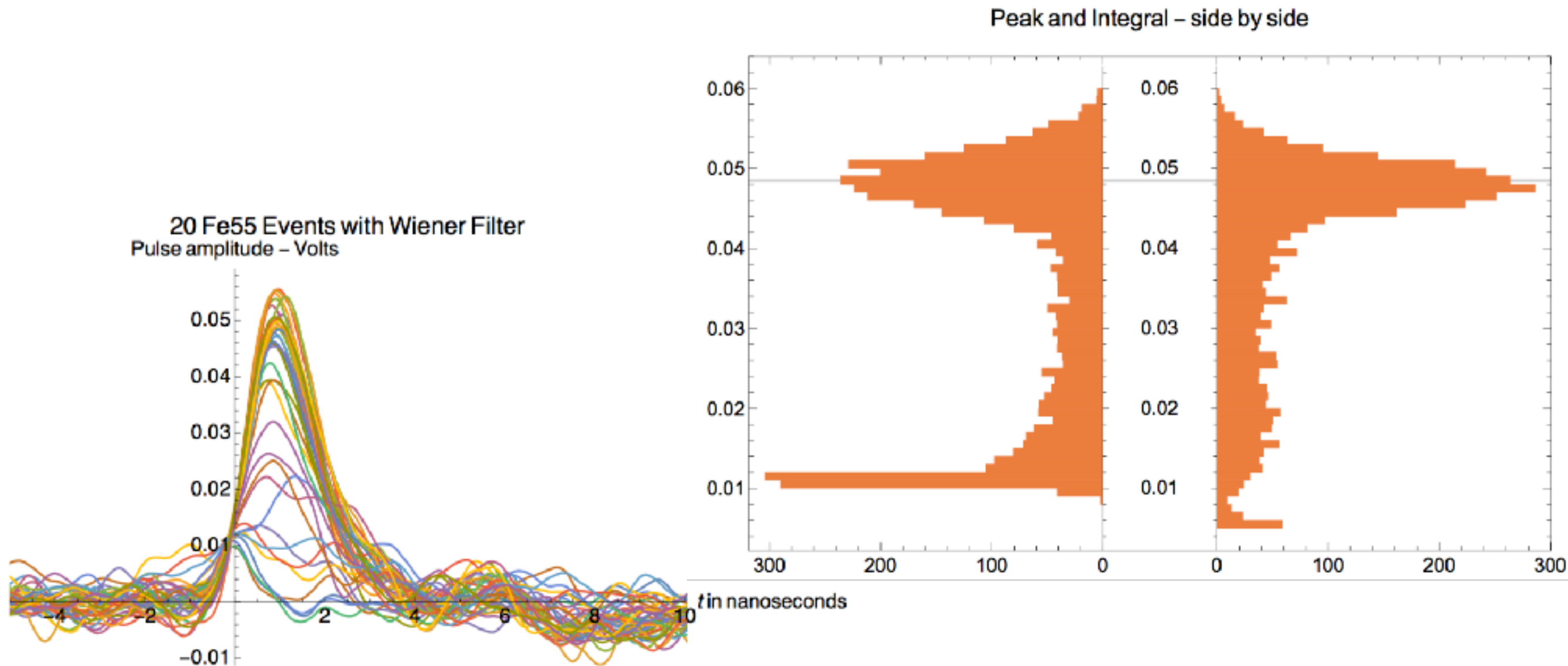
MIP signal ~ 140 mV



peak pulse height distribution
from 5.4 keV Cr X-rays
 $\sim 1/3$ of most probable MIP(150 GeV muons)



routinely adjust laser intensity vs. Fe55 once this equivalence established



Most probable signal for 5.9 keV X-ray (~1600 e-h pairs) easily seen for a given detector bias.
-> set laser intensity for roughly 3* larger signal.
Then vary bias to set different internal gain in HFS.